

VS10C

EVALUATION DATA

DWG No. : CA709-53-01			
APPD	APPD	CHK	DWG
Murayama 31. Aug. '99	K. I. NFT 10. Aug. 99	Rey Aug. 10. '99	shimizu Aug. 06. 99

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Terminology used

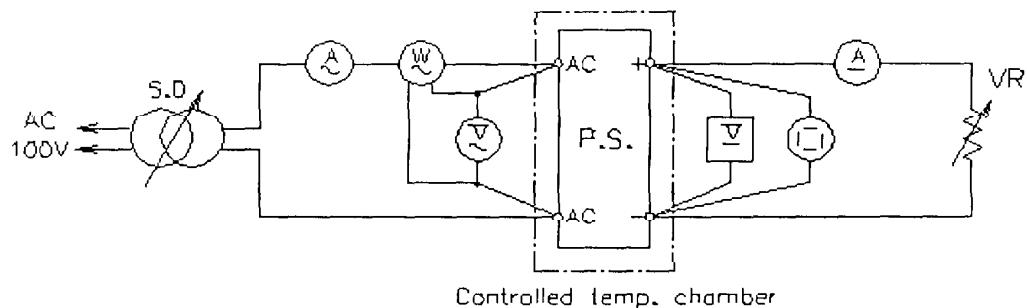
Definition		
V _{in}	Input voltage
V _{out}	Output voltage
I _{in}	Input current
I _{out}	Output current
T _a	Ambient temperature

1. Evaluation Method

VS10C

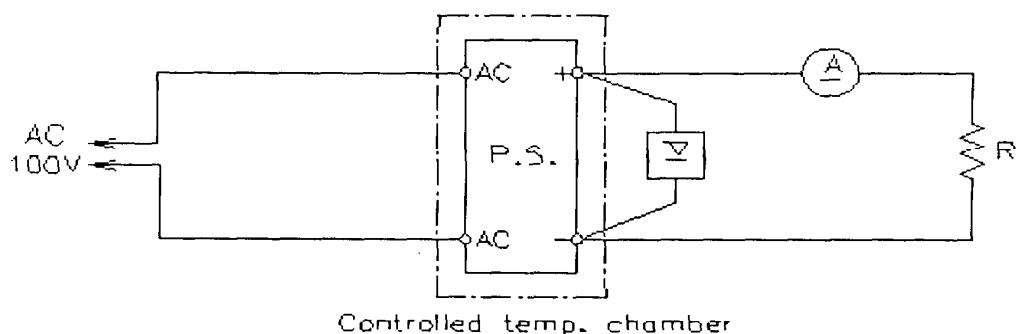
1.1 Circuit used for determination

(1) Steady state data



Controlled temp. chamber

(2) Warm up voltage drift characteristics

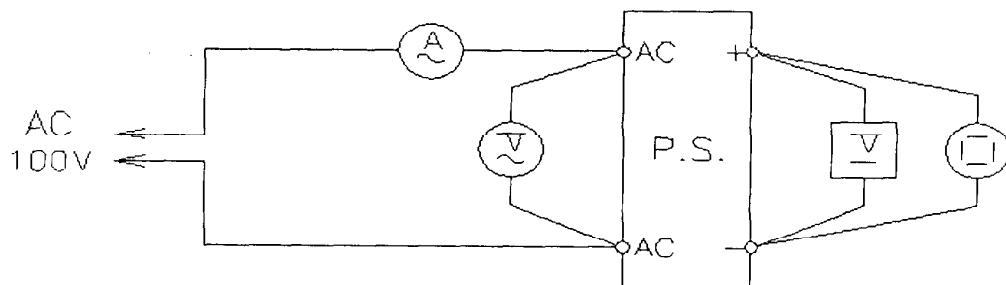


Controlled temp. chamber

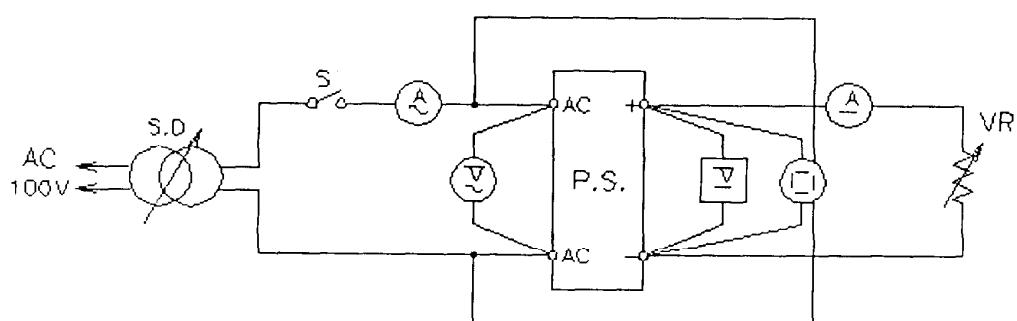
(3) Over current protection (O.C.P) characteristics

Same as Steady state data.

(4) Over voltage protection (O.V.P) characteristics



(5) Output rise characteristics

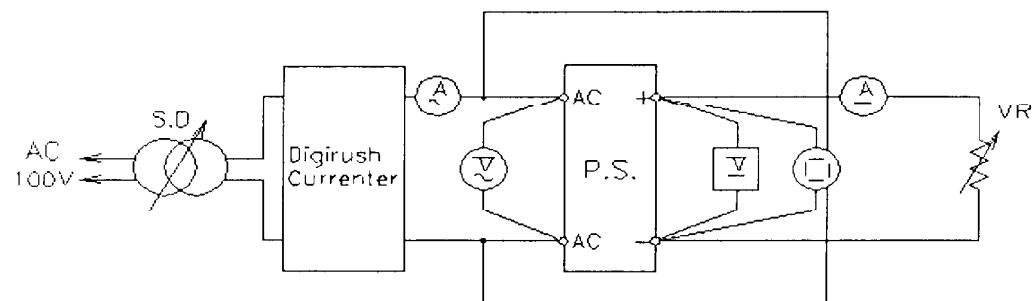


NEMIC-LAMBDA

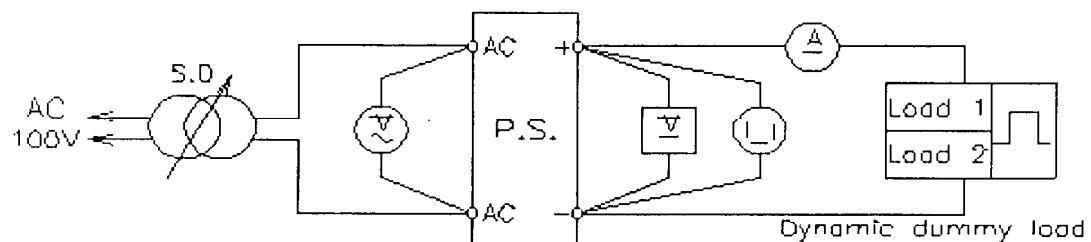
(6) Output fall characteristics

Same as output rise characteristics.

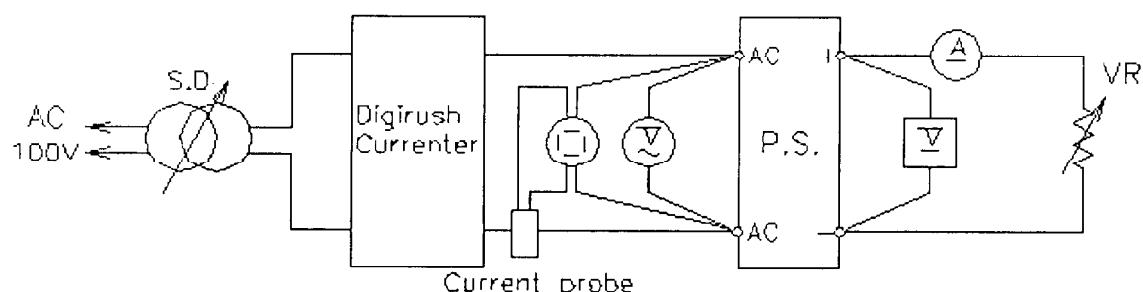
(7) Dynamic line response characteristics



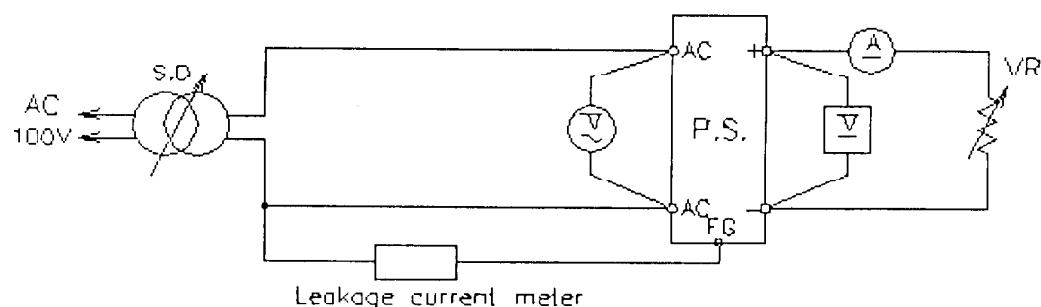
(8) Dynamic load response characteristics



(9) Inrush current characteristics

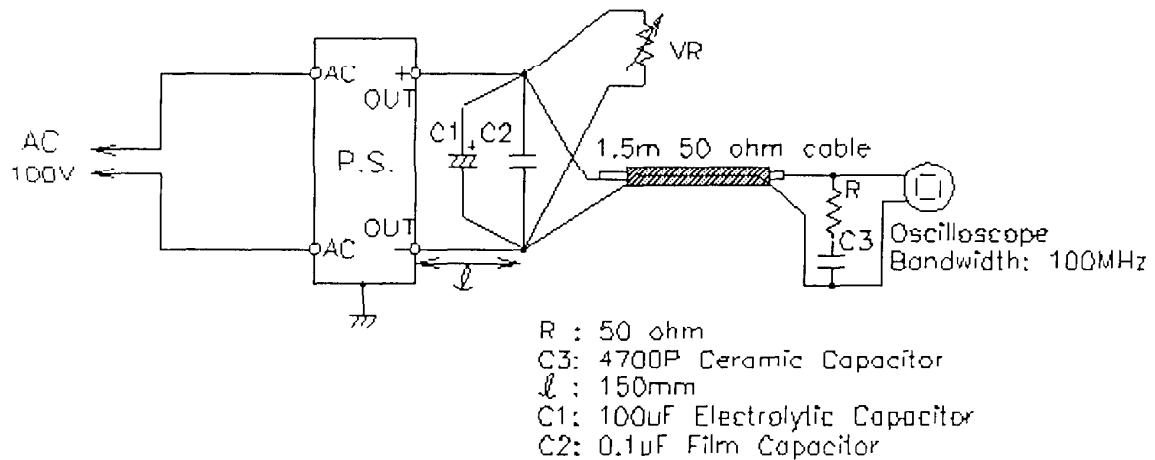


(10) Leakage current characteristics

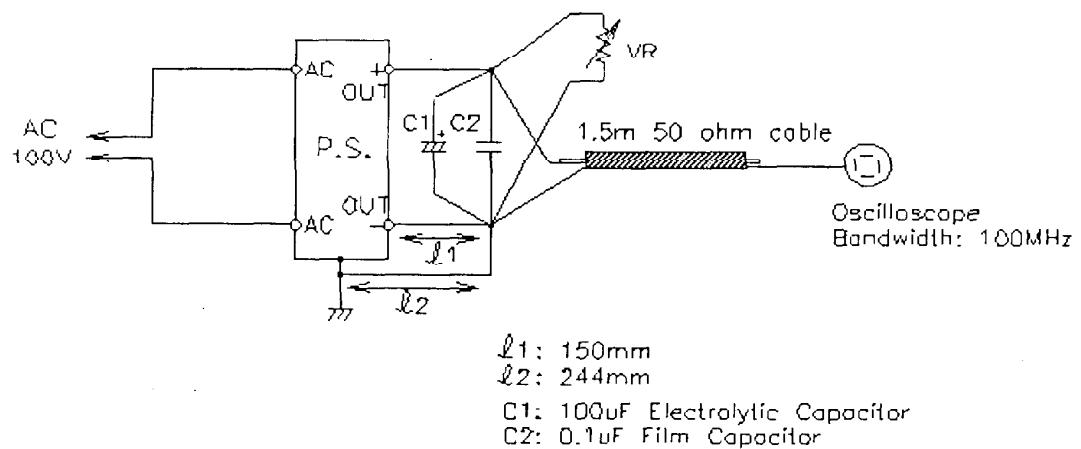


11) Output ripple and noise waveform

a) Normal Mode (EIAJ Standard RC - 9002A)

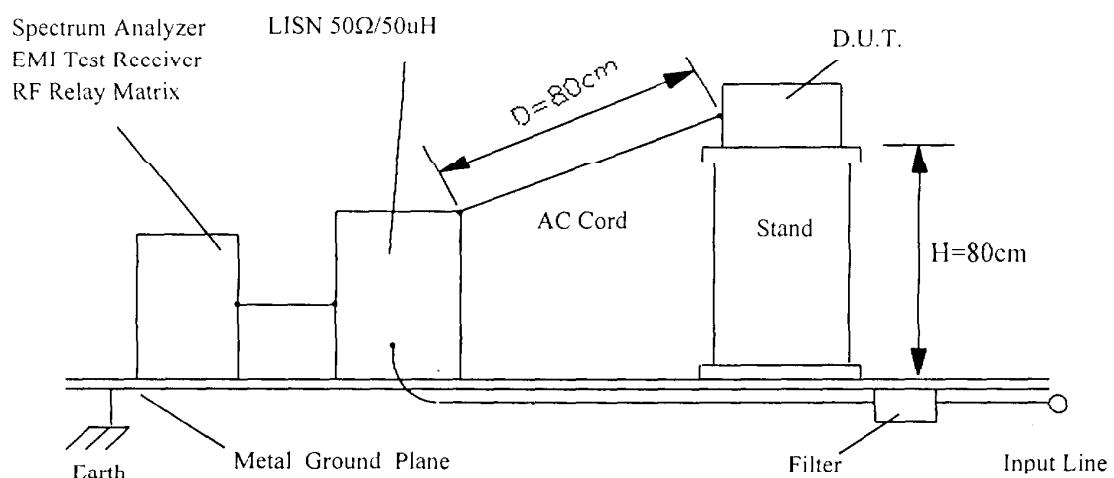


b) Normal + Common Mode

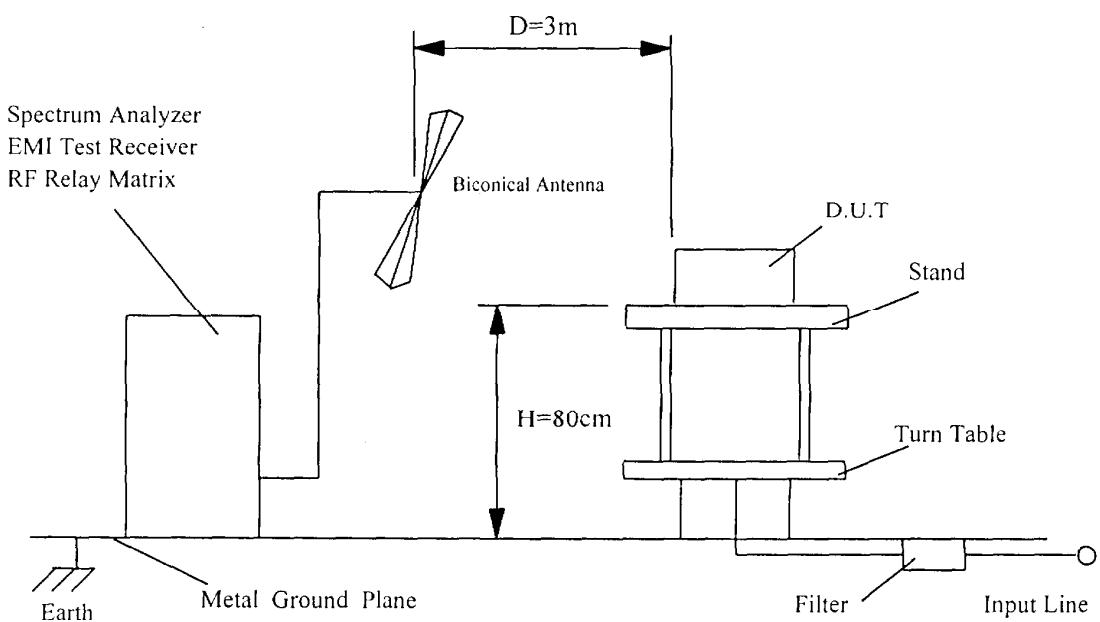


12) Electro-Magnetic Interference characteristics

(a) Conducted Emission Noise



(b) Radiated Emission Noise



1.2 LIST OF EQUIPMENT USED

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	Oscilloscope	HITACHI	V-1050
2	Digital storage oscilloscope	TEKTRONIX	TDS-540A
3	Digital volt meter	LEADER	856
4	Digital watt/current/volt meter	HIOKI	3186
5	DC ampere meter	YOKOGAWA	2051
6	Dynamic dummy load	KIKUSUI	PLZ152W
7	Current probe/amplifier	TEKTRONIX	A6303/AM503B
8	Controlled temperature chamber	TABAI-ESPEC	SU-240
9	Leakage current meter	SIMPSON	228
10	Digirush curreneter	TAKAMISAWA CYBERNETICS	PSA-200

2. Characteristics

2.1 Steady state data

(1) Regulation - line and load, temperature drift

5V

1. Regulation - line and load

Condition Ta : 25°C

Iout\Vin	85V	100V	132V	Line regulation	
0%	5.018	5.018	5.016	2 mV	0.04%
50%	5.017	5.016	5.015	2 mV	0.04%
100%	5.012	5.013	5.014	2 mV	0.04%
Load Regulation	6 mV	5 mV	2 mV		
	0.12%	0.10%	0.04%		

2. Temperature drift

Conditions Vin=100Vac

Io =100%

Ta(°C)	-10°C	+25°C	+50°C	Temperature drift	
	5.029	5.013	5.023	16 mV	0.32%

12V

1. Regulation - line and load

Condition Ta : 25°C

Iout\Vin	85V	100V	132V	Line regulation	
0%	12.044	12.041	12.042	3 mV	0.025%
50%	12.038	12.038	12.036	2 mV	0.017%
100%	12.035	12.031	12.036	5 mV	0.042%
Load Regulation	9 mV	10 mV	6 mV		
	0.075%	0.083%	0.050%		

2. Temperature drift

Conditions Vin=100Vac

Io =100%

Ta(°C)	-10°C	+25°C	+50°C	Temperature drift	
	12.012	12.031	12.057	45 mV	0.375%

24V

1. Regulation - line and load

Condition Ta : 25°C

Iout\Vin	85V	100V	132V	Line regulation	
0%	24.092	24.091	24.093	2 mV	0.008%
50%	24.085	24.078	24.075	10 mV	0.042%
100%	24.081	24.078	24.072	9 mV	0.038%
Load Regulation	11 mV	13 mV	21 mV		
	0.046%	0.054%	0.088%		

2. Temperature drift

Conditions Vin=100Vac

Io =100%

Ta(°C)	-10°C	+25°C	+50°C	Temperature drift	
	24.163	24.078	24.086	85 mV	0.354%

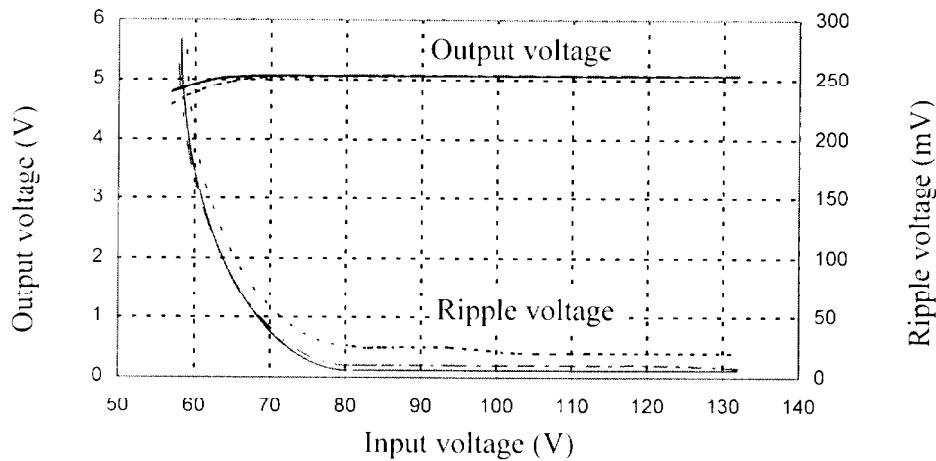
VS10C

2.1. (2) Output voltage and Ripple voltage v.s. Input voltage

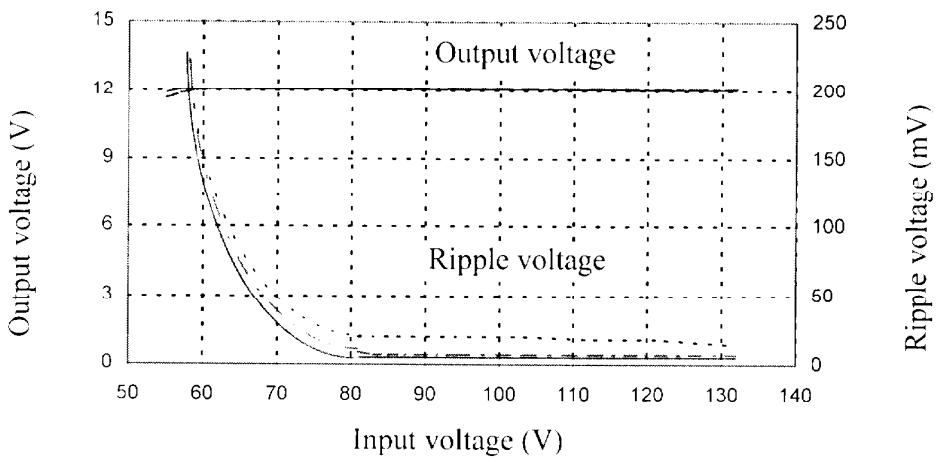
Conditions Iout : 100%

T_a : -10°C
25°C
50°C _____

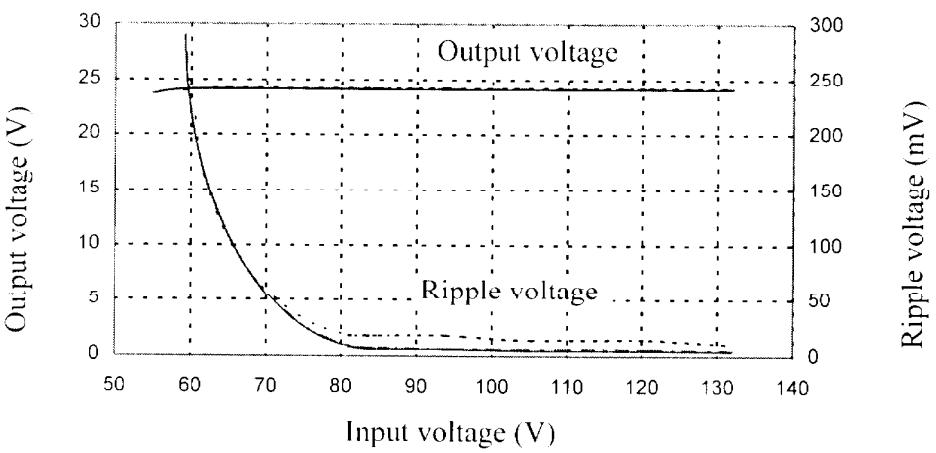
5V



12V



24V

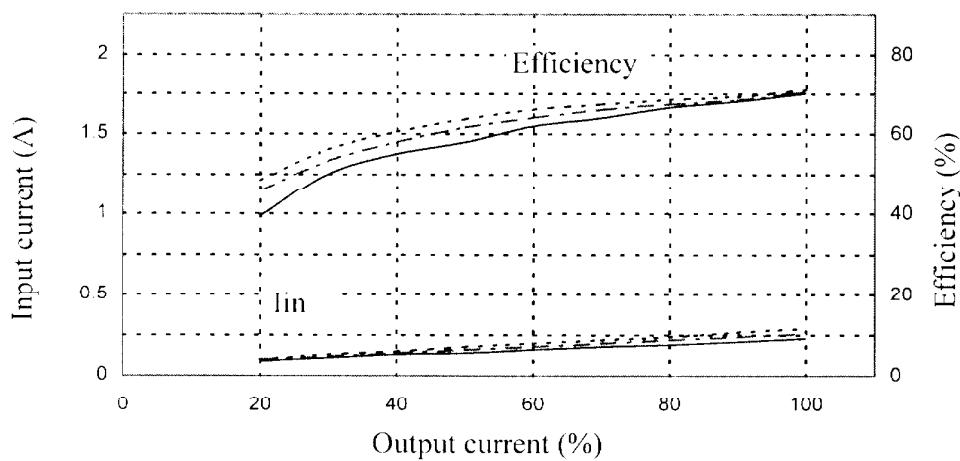


2.1. (3) Efficiency and Input current v.s. Output current

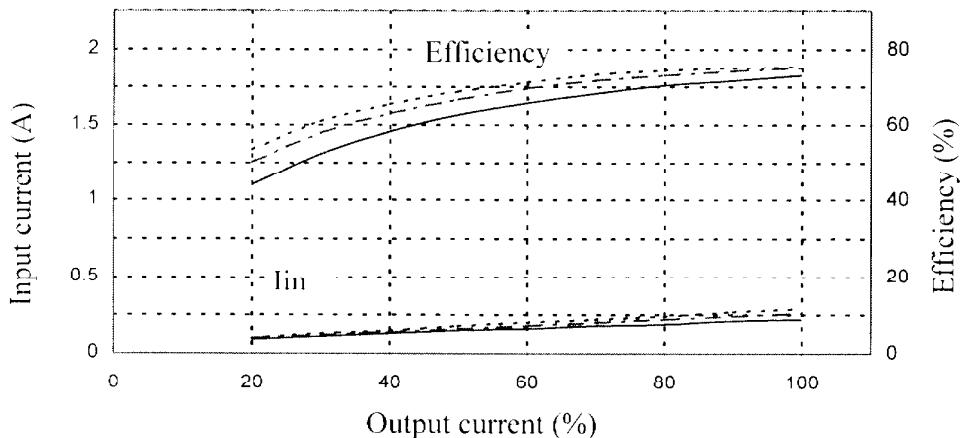
Conditions Ta : 25°C

Vin : 85Vac
 100Vac - - - - -
 132Vac ——————

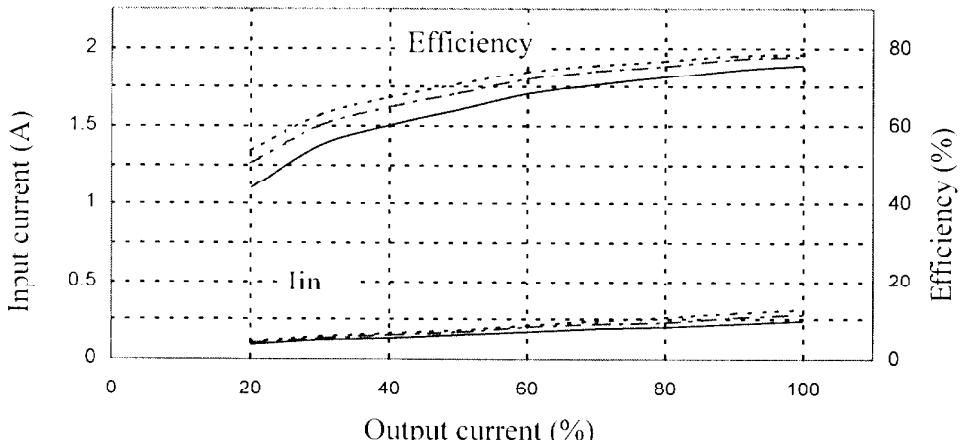
5V



12V



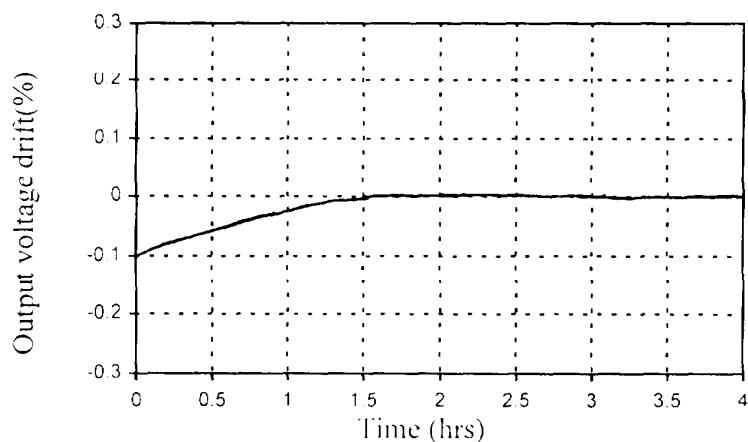
24V



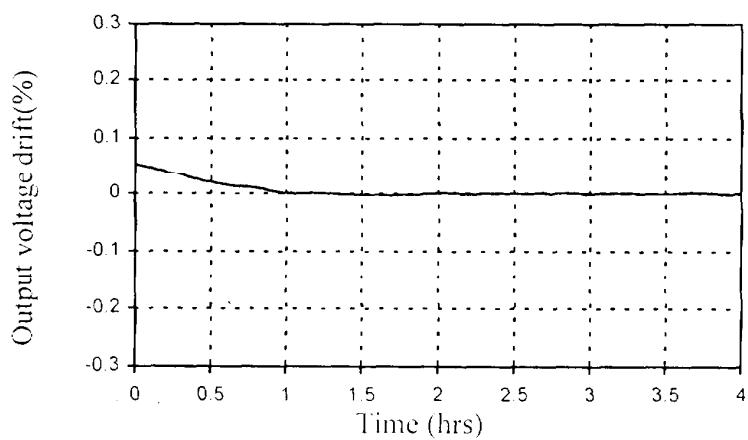
2.2 Warm up voltage drift characteristics

Conditions Vin : 100VAC
 Iout : 100%
 Ta : 25°C

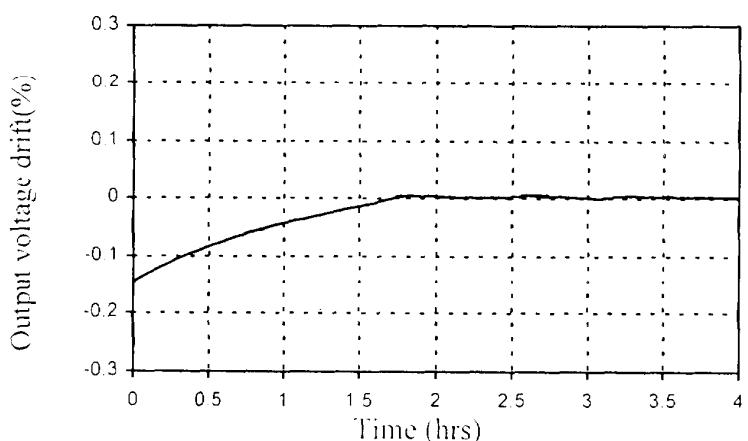
5V



12V



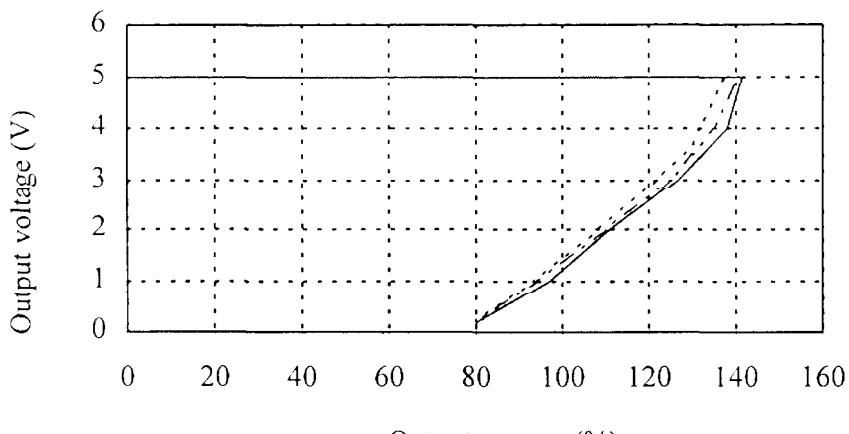
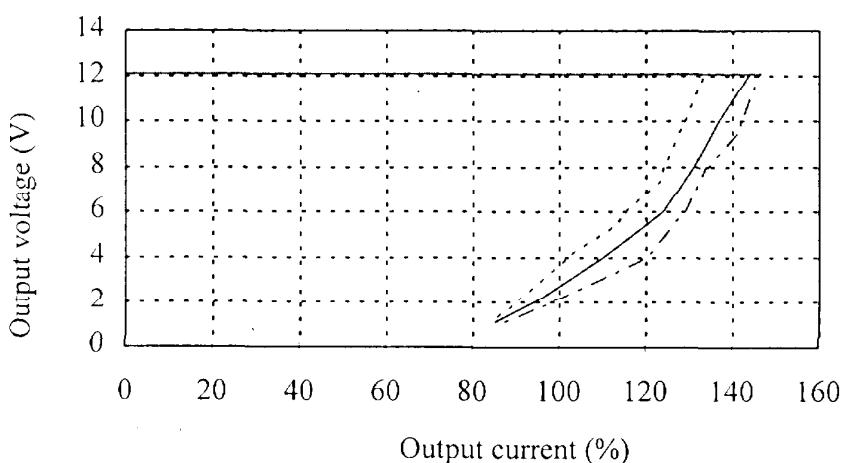
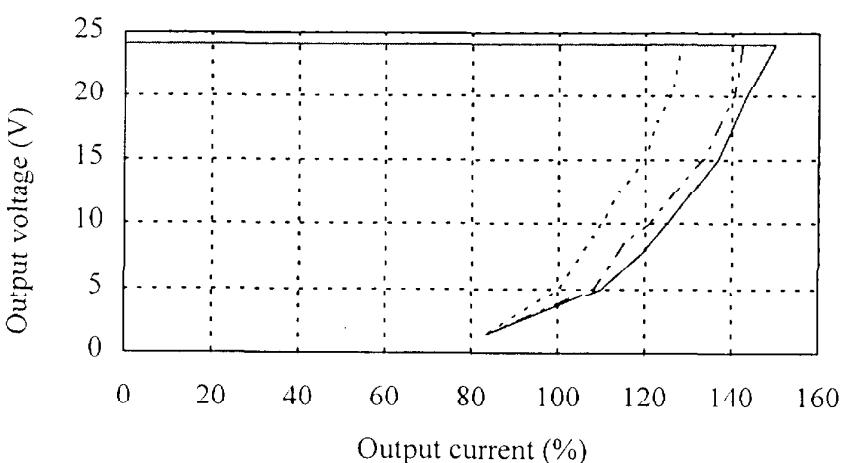
24V



2.3 Over current protection (OCP) characteristics

Conditions Ta : 25°C

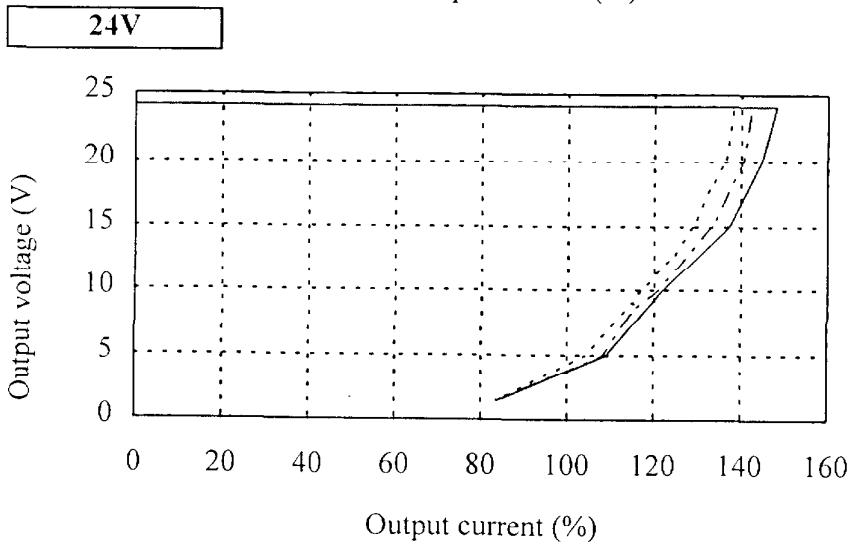
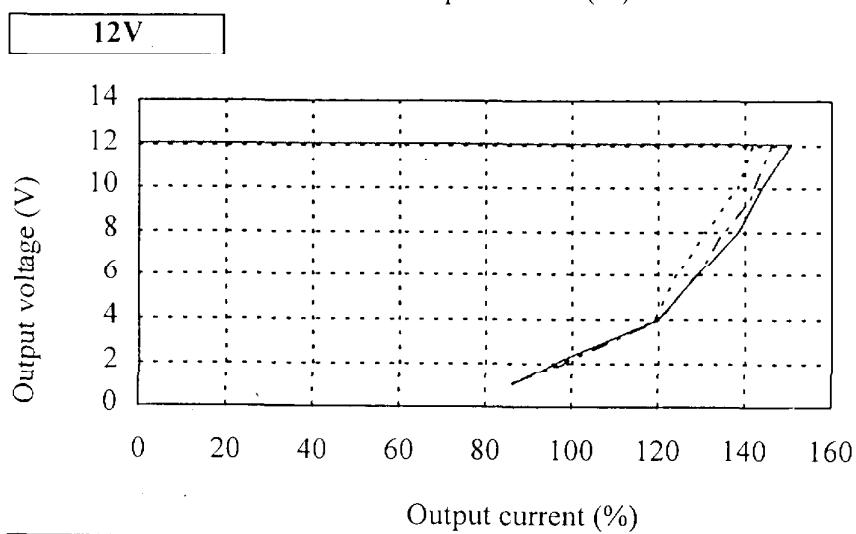
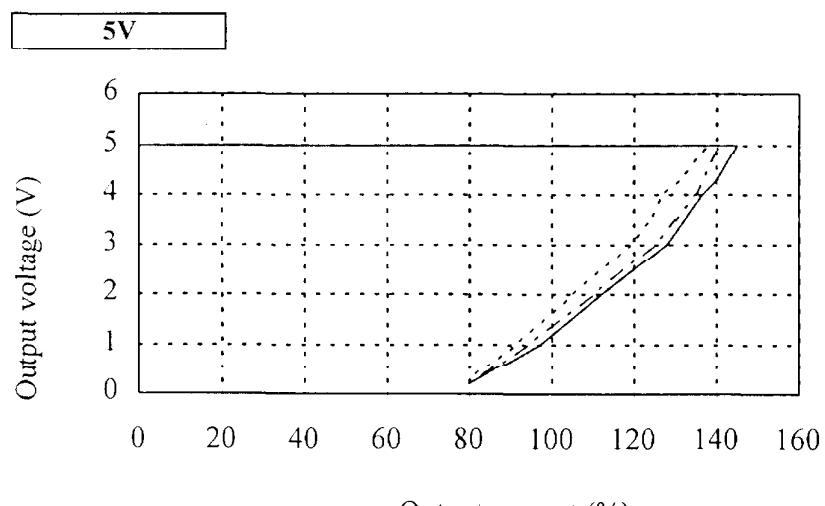
Vin : 85Vac
 100Vac - - - - -
 132Vac —————

5V**12V****24V**

2.3 Over current protection (OCP) characteristics

Conditions Vin : 100VAC

T_a : -10°C
 25°C -----
 50°C ———



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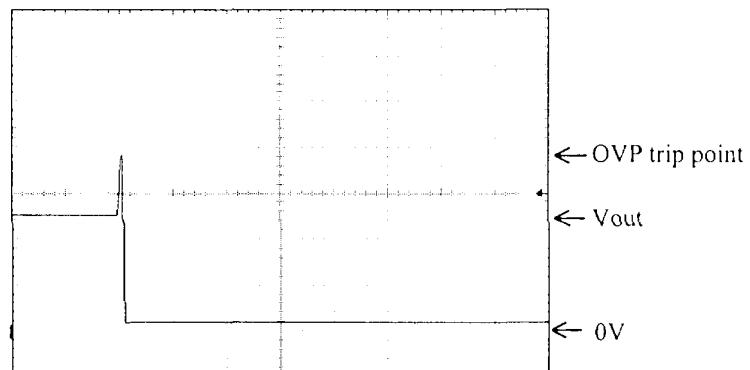
Conditions Ta : 25°C

Vin : 100Vac

Io : 0%

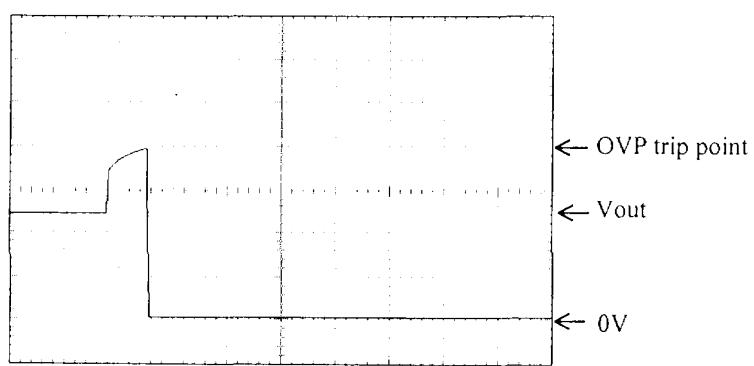
2.4 Over voltage protection (OVP) characteristics

5V



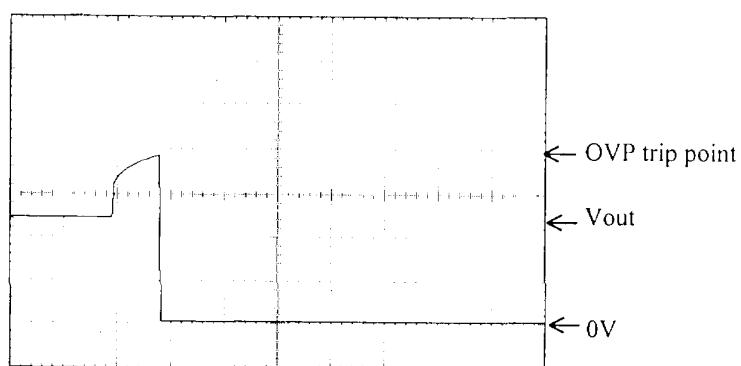
2V/DIV 200mS/DIV

12V



5V/DIV 200mS/DIV

24V



10V/DIV 200mS/DIV

VS10C

2.5 Output rise characteristics

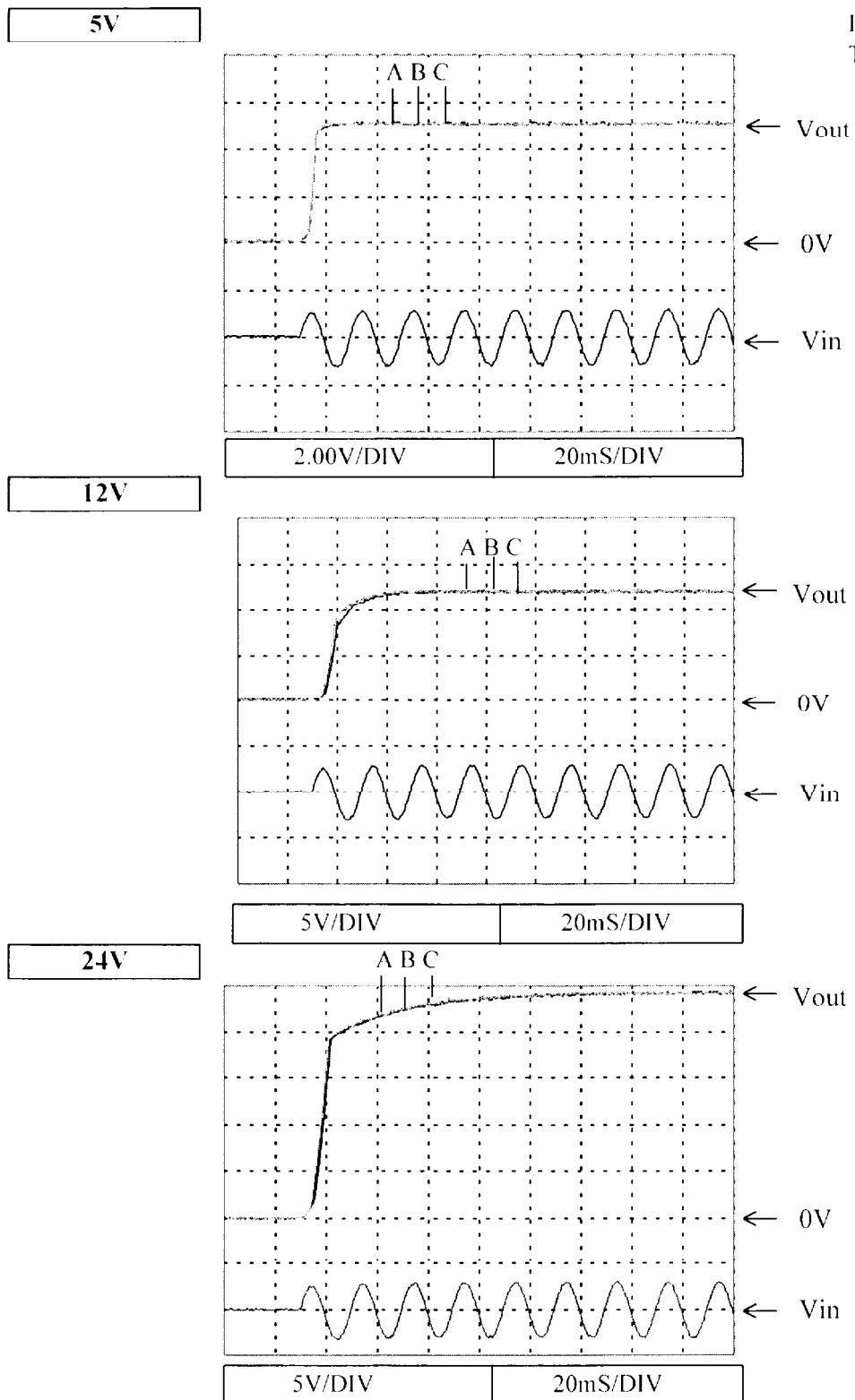
Conditions Vin : 85Vac (A)

: 100Vac (B)

: 132Vac (C)

Iout : 0%

Ta : 25°C



VS10C

2.5 Output rise characteristics

Conditions Vin : 85Vac (A)

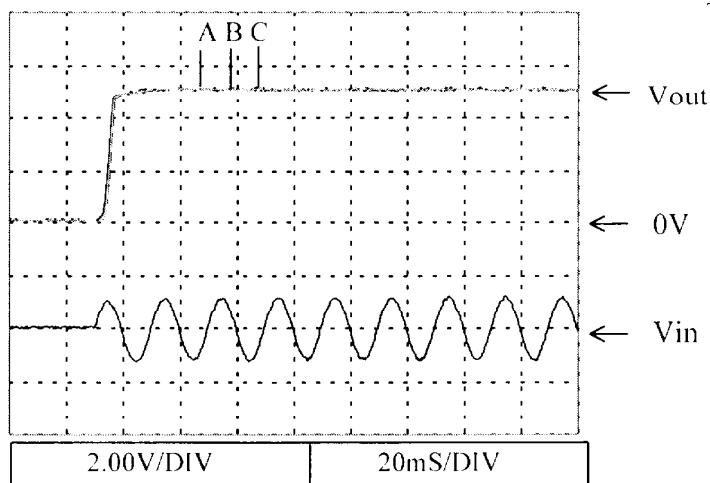
: 100Vac (B)

: 132Vac (C)

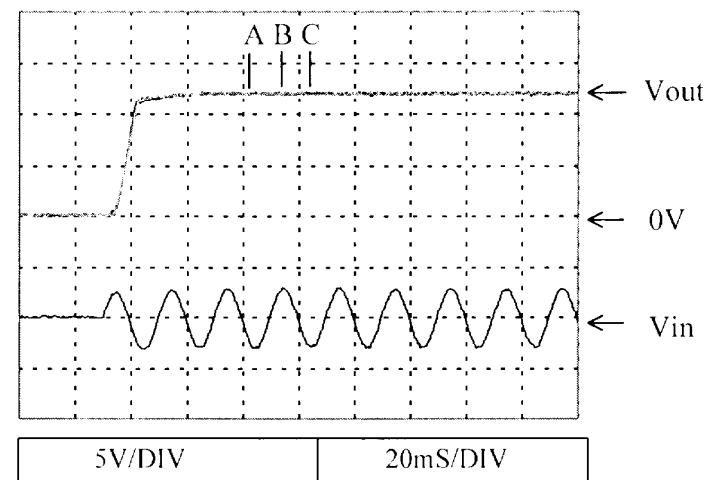
Iout : 100%

Ta : 25°C

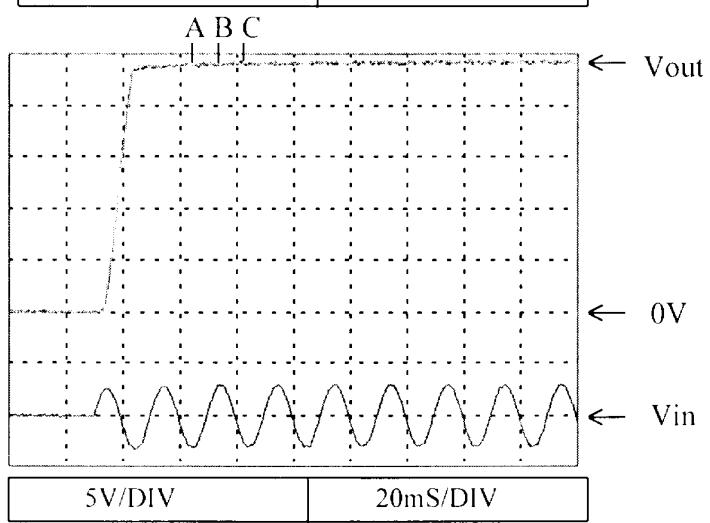
5V



12V



24V



VS10C

Conditions Vin : 85Vac (A)

: 100Vac (B)

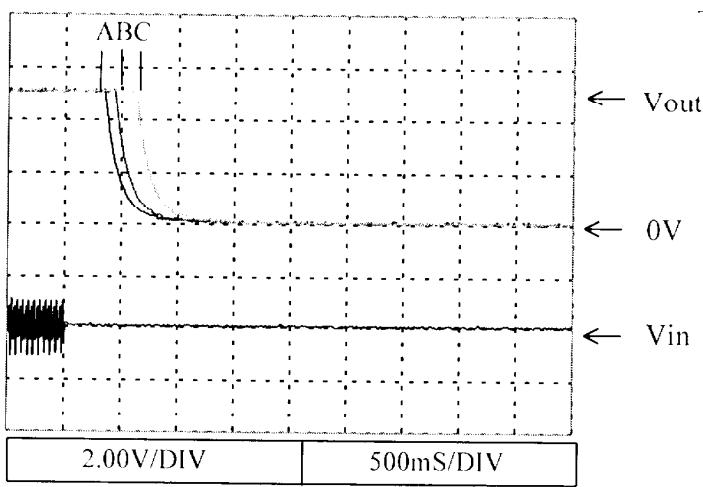
: 132Vac (C)

Iout : 0%

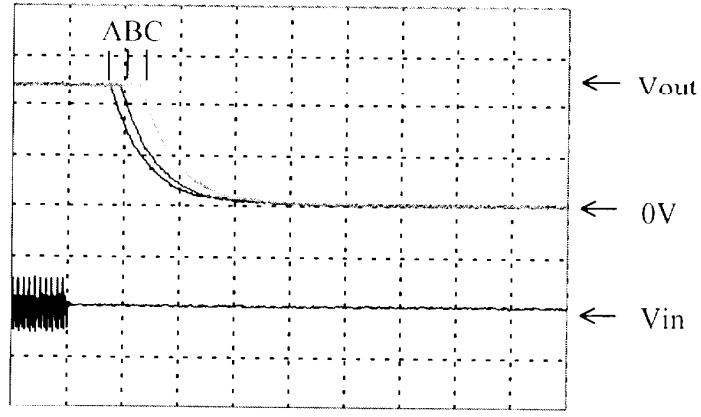
Ta : 25°C

2.6 Output fall characteristics

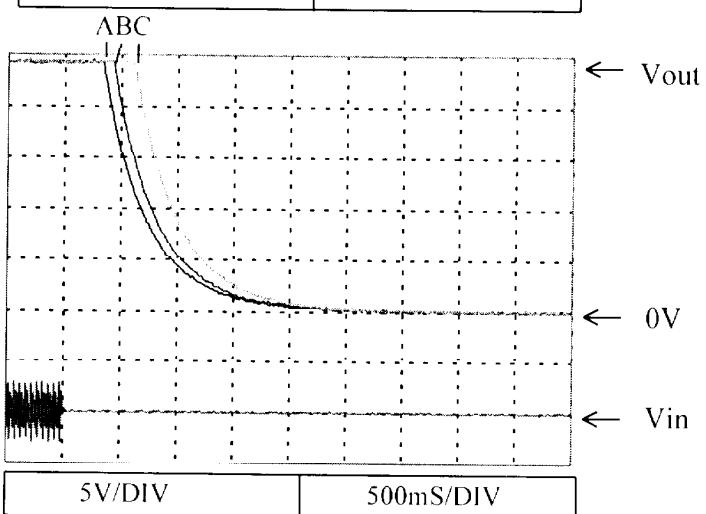
5V



12V



24V



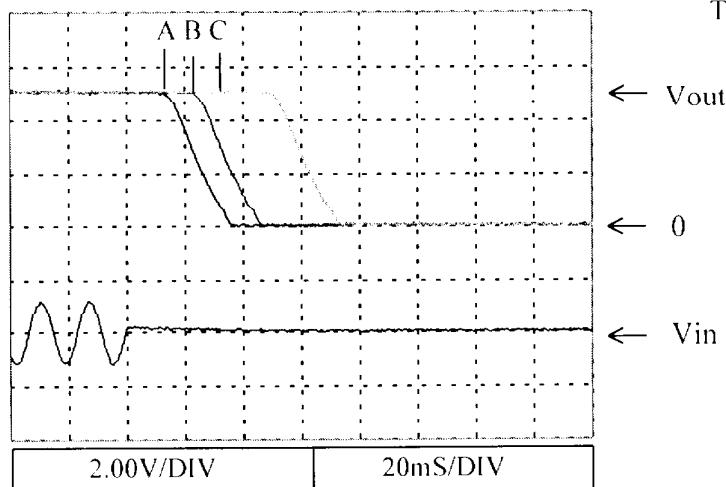
VS10C

2.6 Output fall characteristics

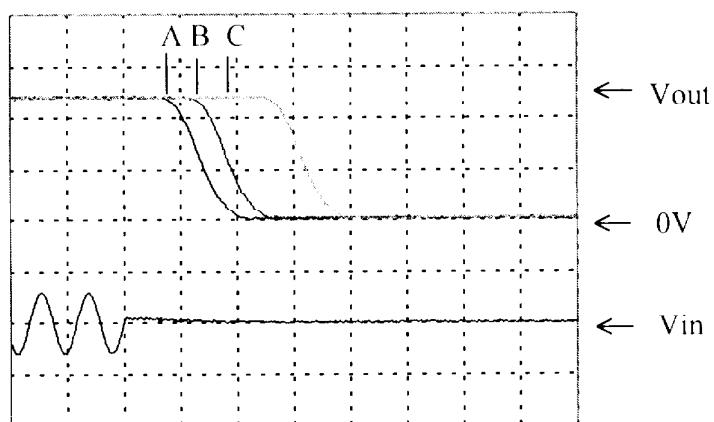
Conditions Vin : 85Vac (A)
: 100Vac (B)
: 132Vac (C)

Iout : 100%
Ta : 25°C

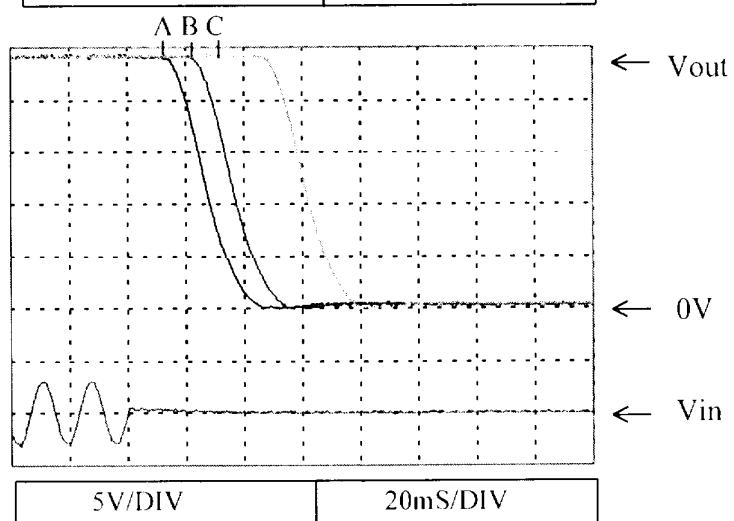
5V



12V



24V



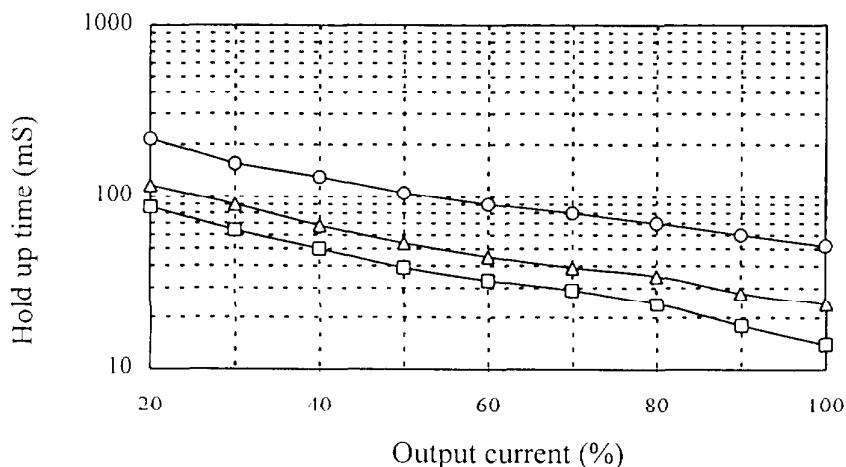
2.7 Hold up time characteristics

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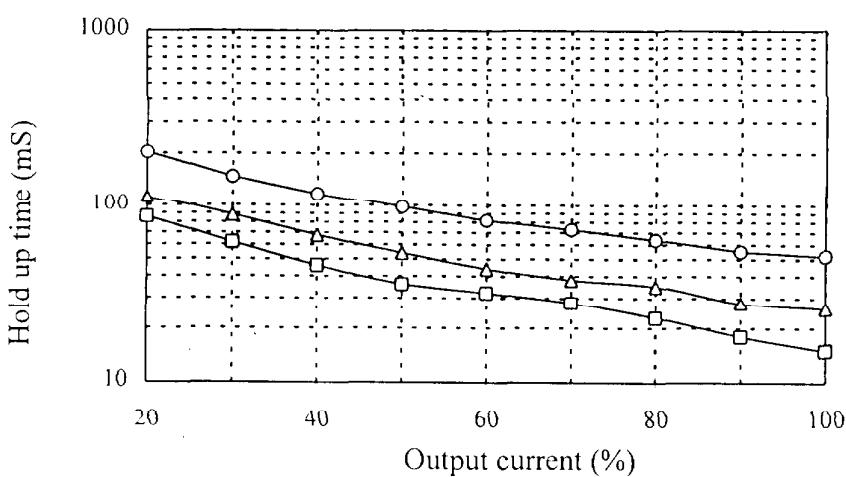
Conditions Ta : 25°C

Vin : 85Vac
 100Vac
 132Vac

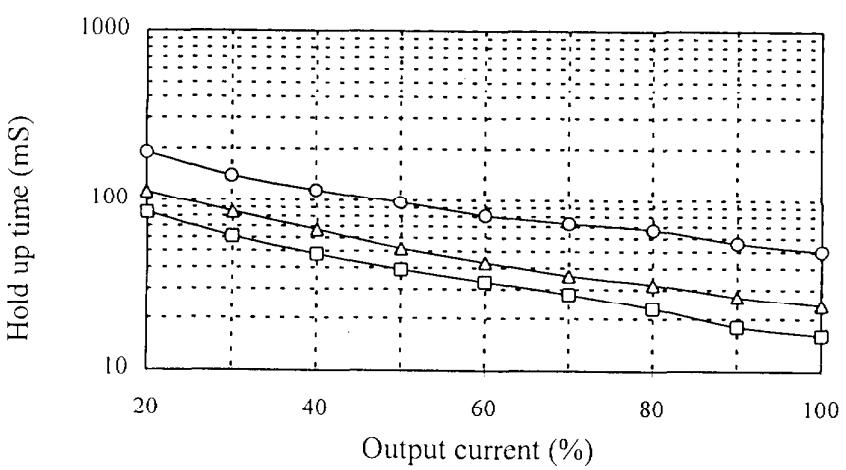
5V



12V



24V



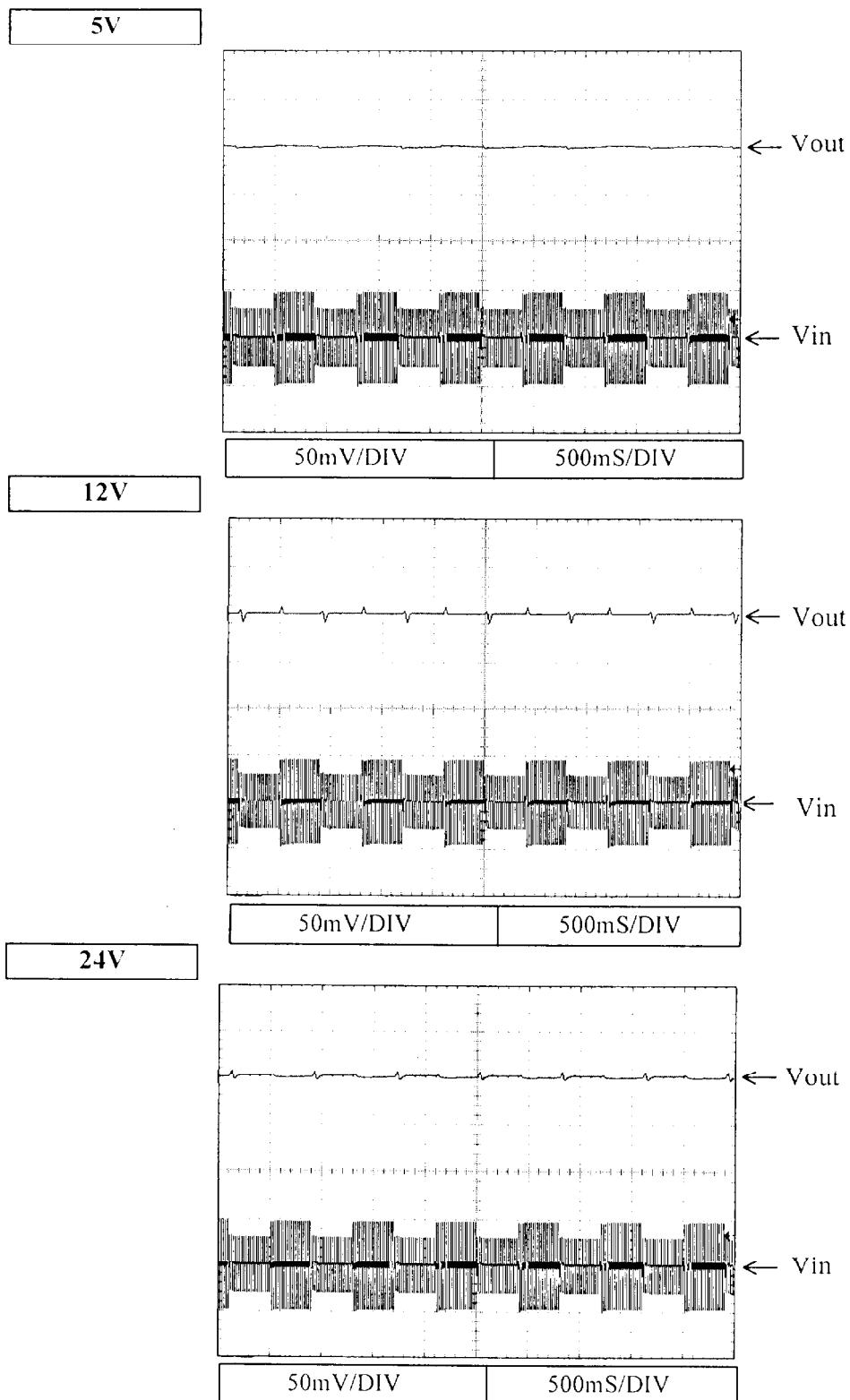
VS10C

2.8 Dynamic line response characteristics

Conditions Vin : 85Vac—132Vac

Iout : 100%

Ta : 25°C

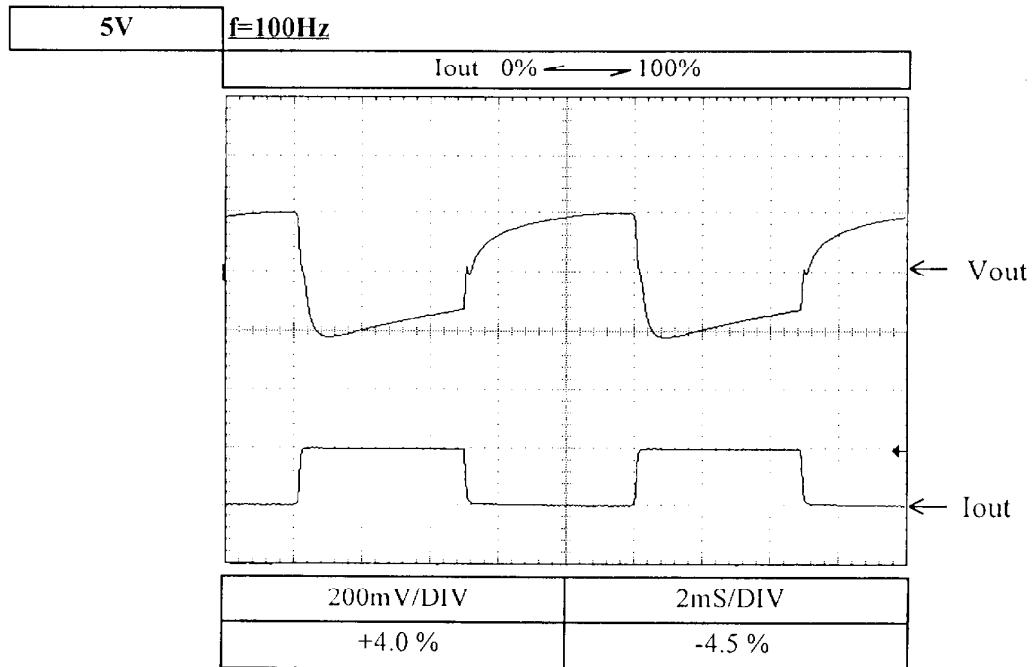


VS10C

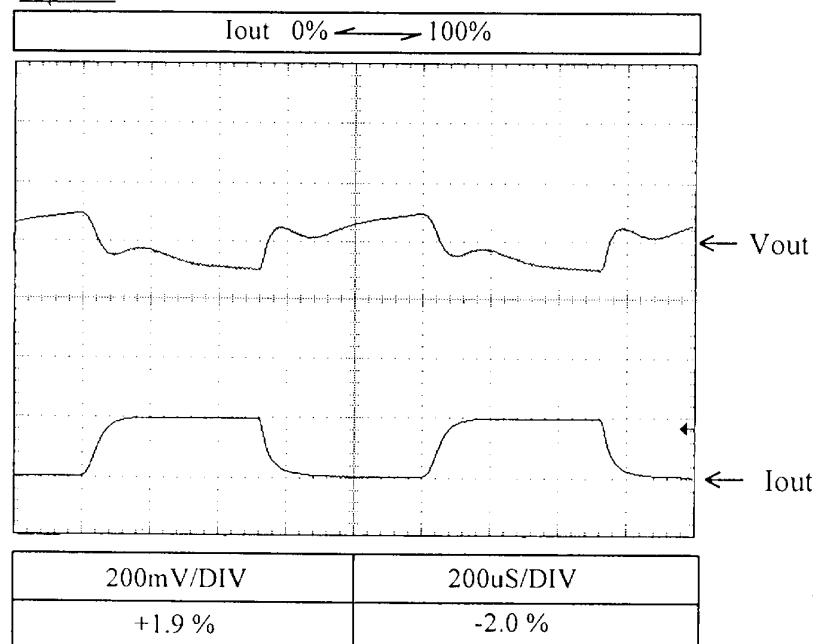
Conditions Vin : 100Vac

T_a : 25°C

2.9 Dynamic load response characteristics



f=1kHz

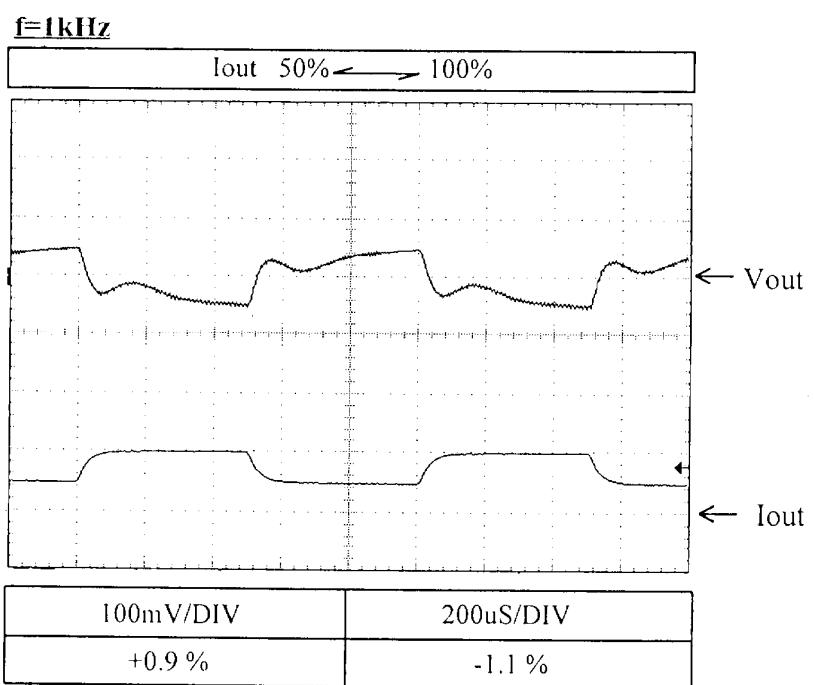
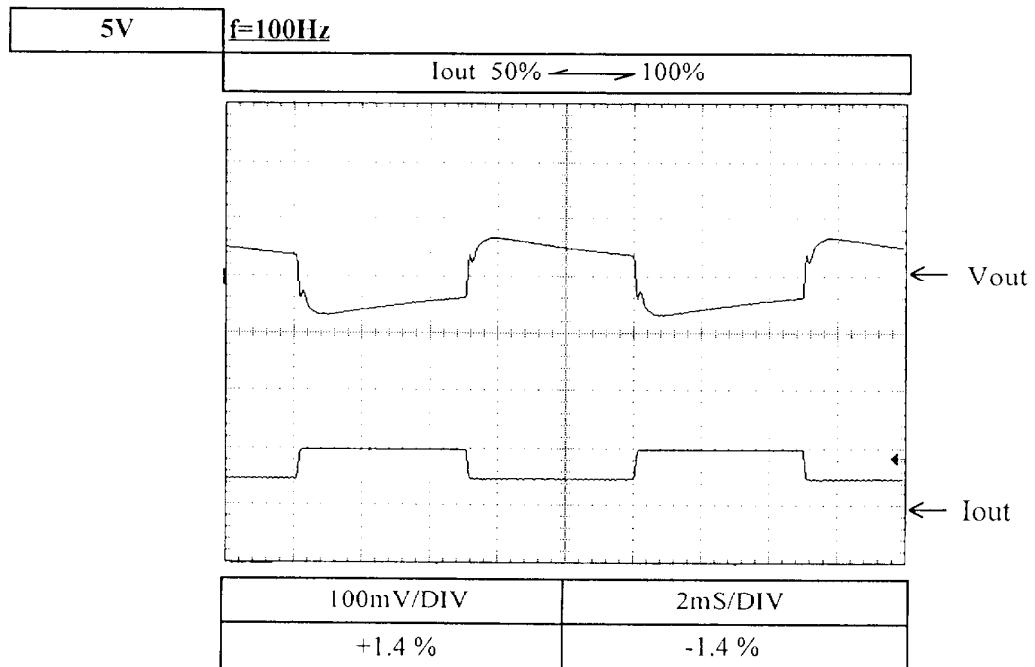


VS10C

2.9 Dynamic load response characteristics

Conditions Vin : 100Vac

T_a : 25°C

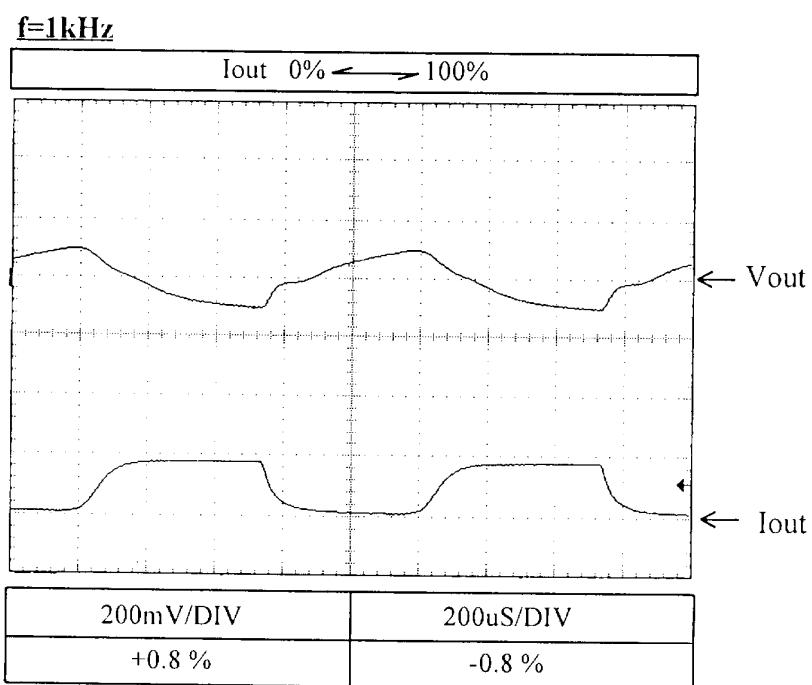
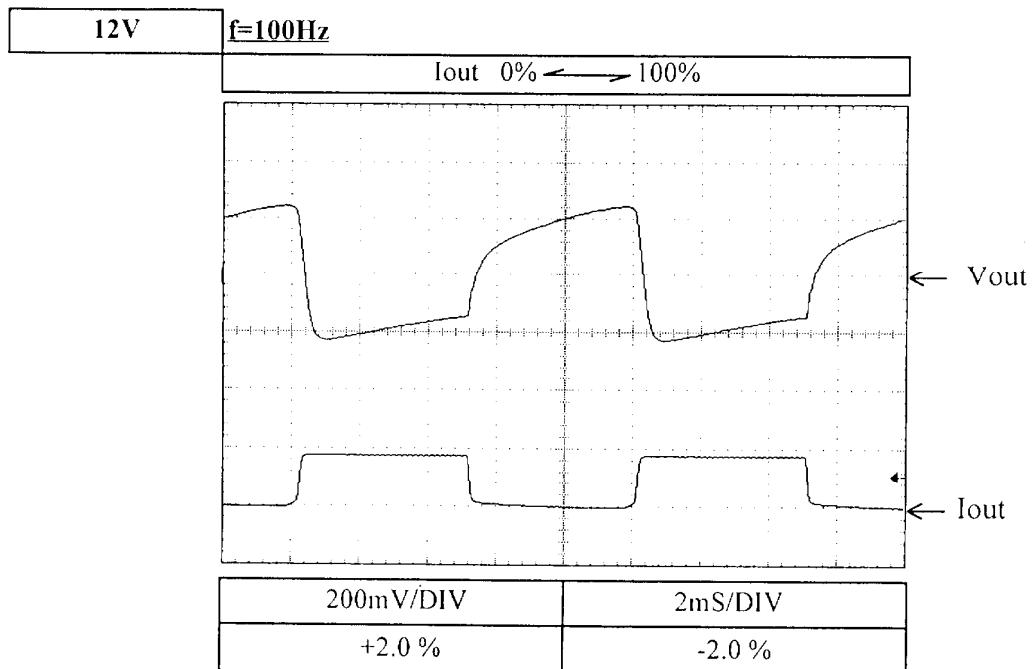


VS10C

2.9 Dynamic load response characteristics

Conditions Vin : 100Vac

Ta : 25°C

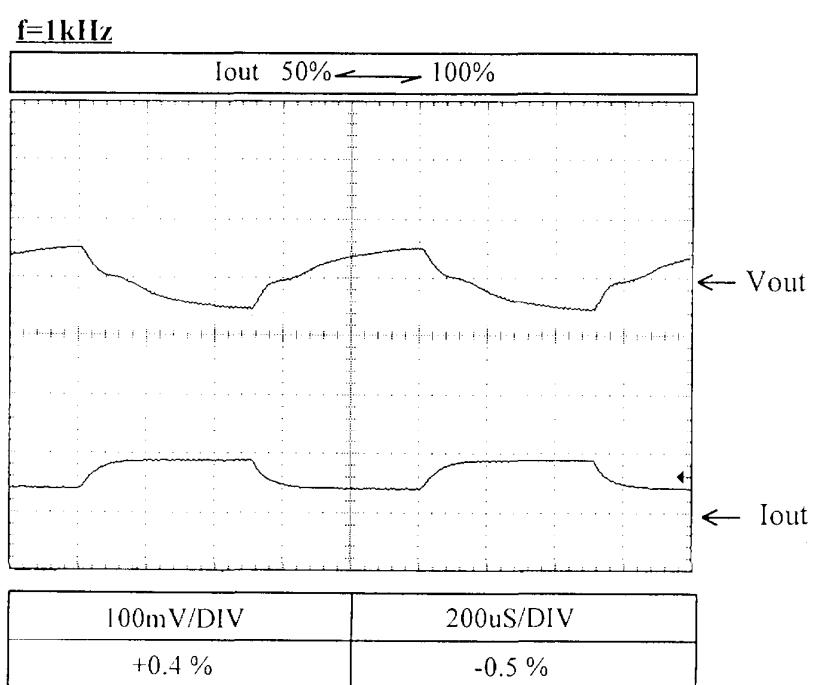
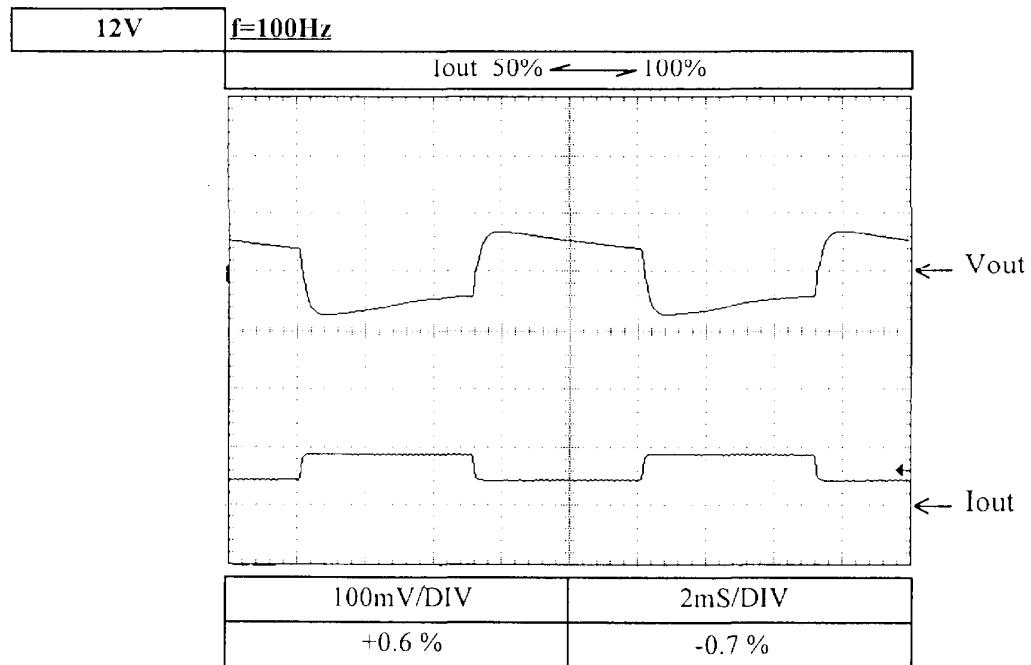


VS10C

2.9 Dynamic load response characteristics

Conditions Vin : 100Vac

T_a : 25°C

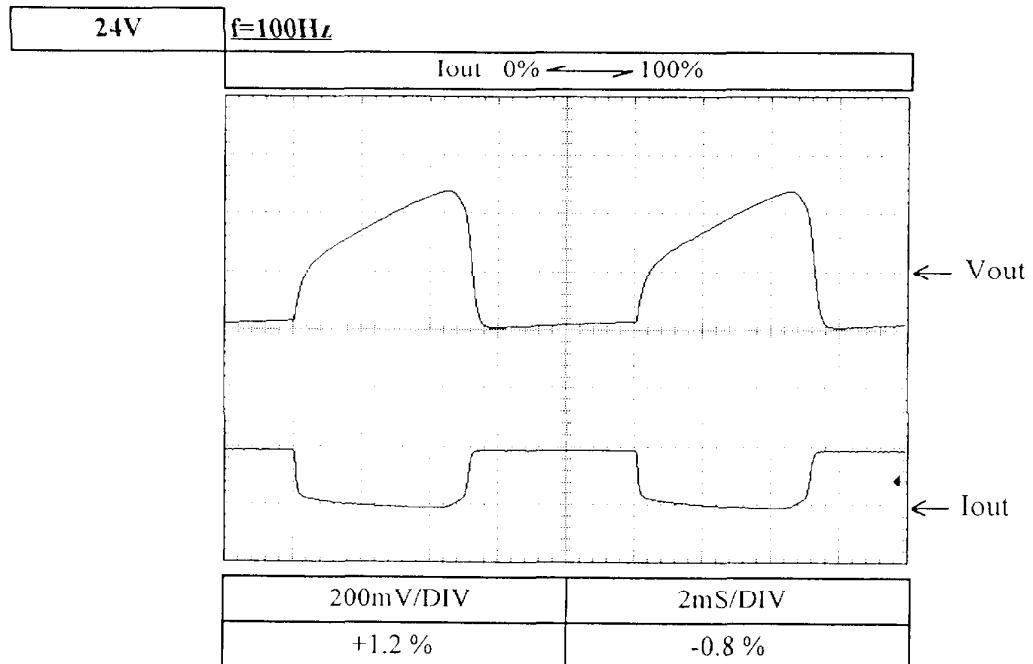


VS10C

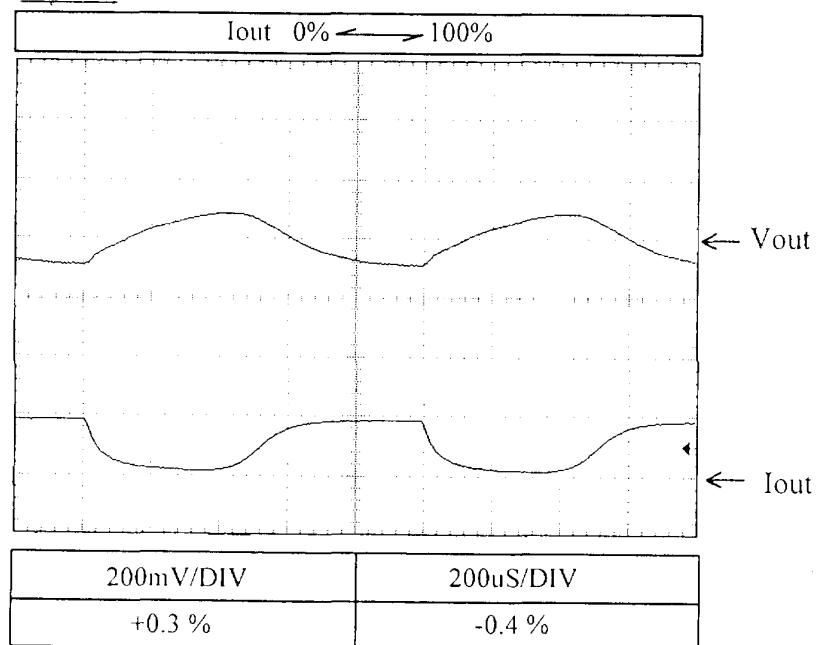
Conditions Vin : 100Vac

T_a : 25°C

2.9 Dynamic load response characteristics



f=1kHz

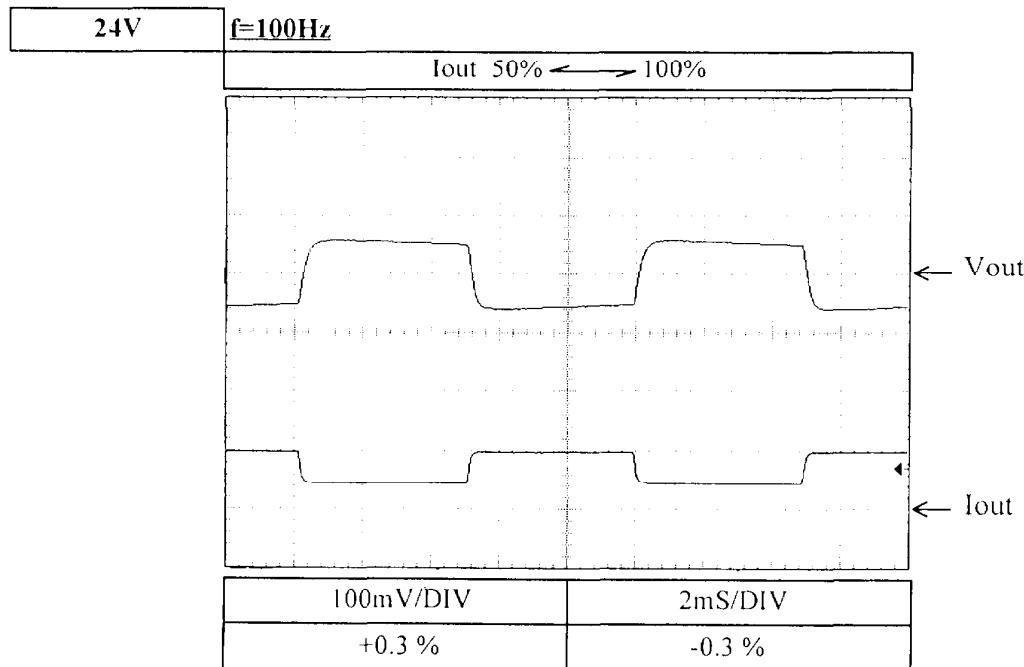


VS10C

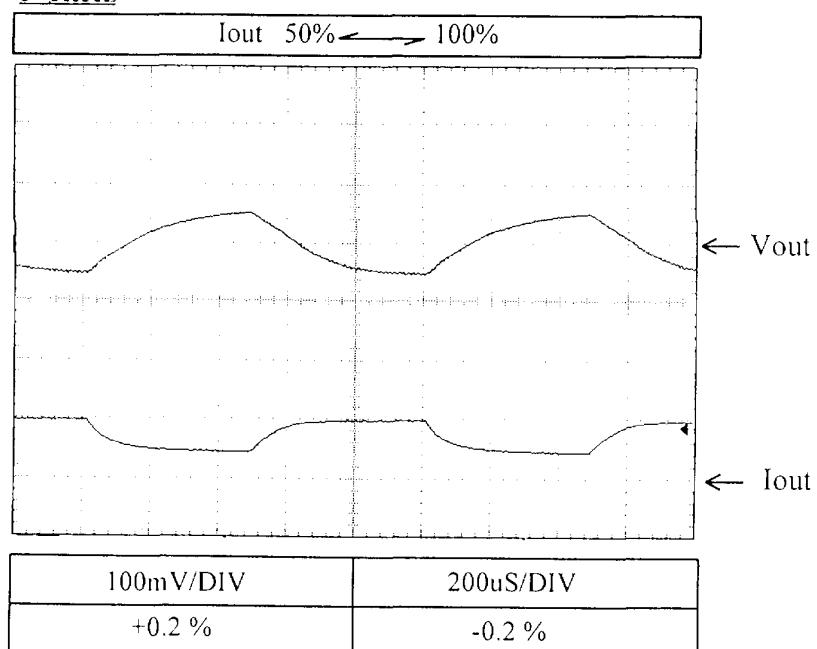
2.9 Dynamic load response characteristics

Conditions Vin : 100Vac

T_a : 25°C



f=1kHz



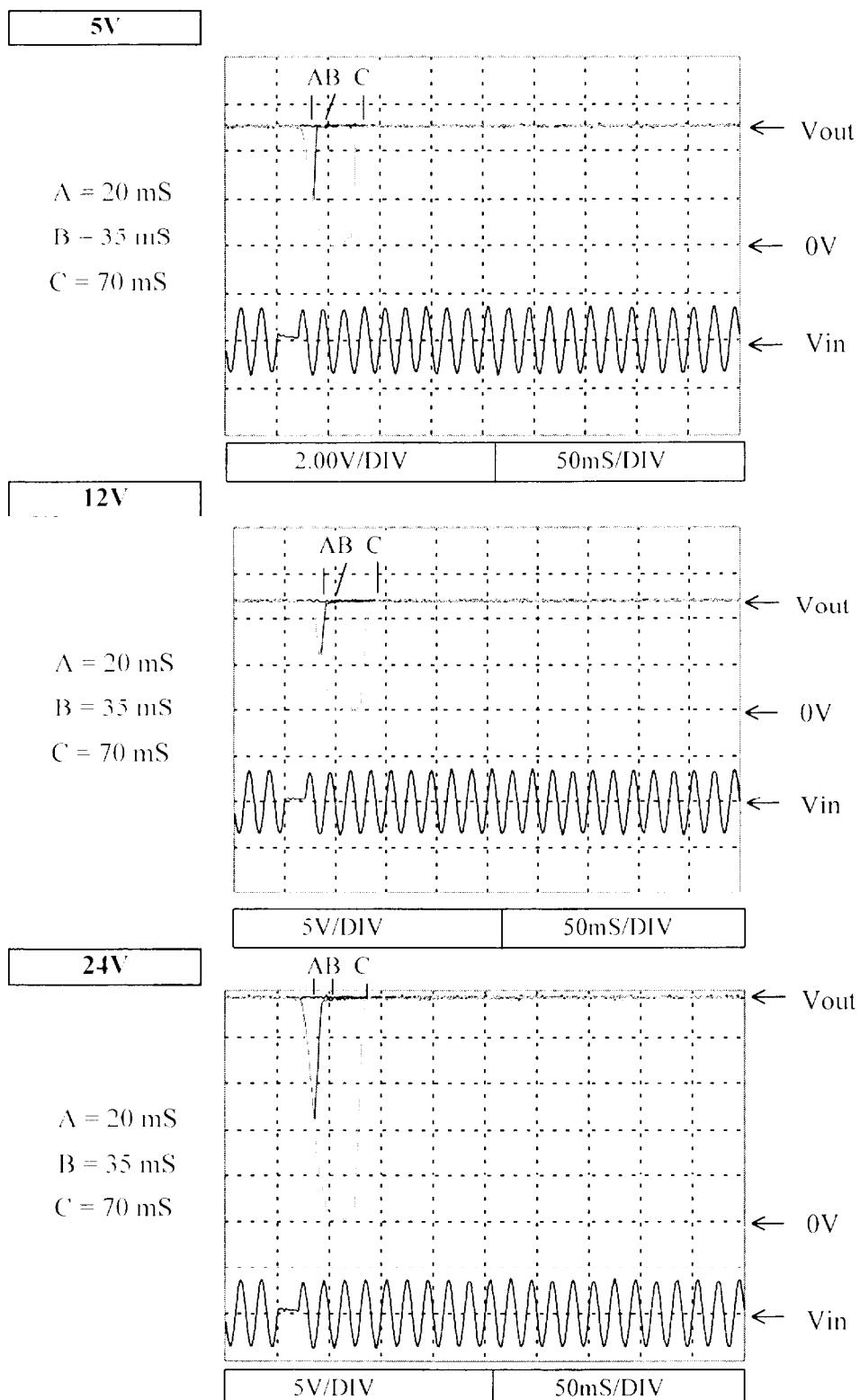
VS10C

2.10 Response to brown out characteristics

Conditions Vin : 100Vac

Iout : 100%

Ta : 25°C



VS10C

2.11 Inrush current waveform

Conditions Vin : 100Vac

Iout : 100%

Ta : 25°C

5V

Switch on phase
angle of input
AC voltage :

$$\Phi=0^\circ$$

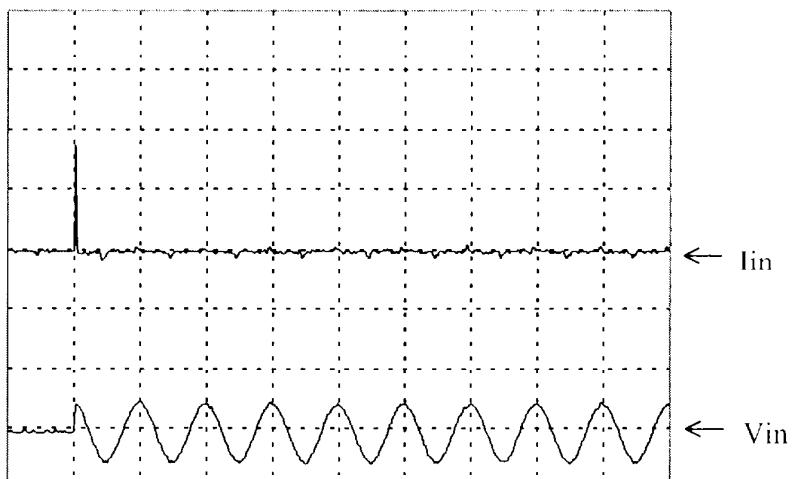


5.0A/DIV

20mS/DIV

Switch on phase
angle of input
AC voltage :

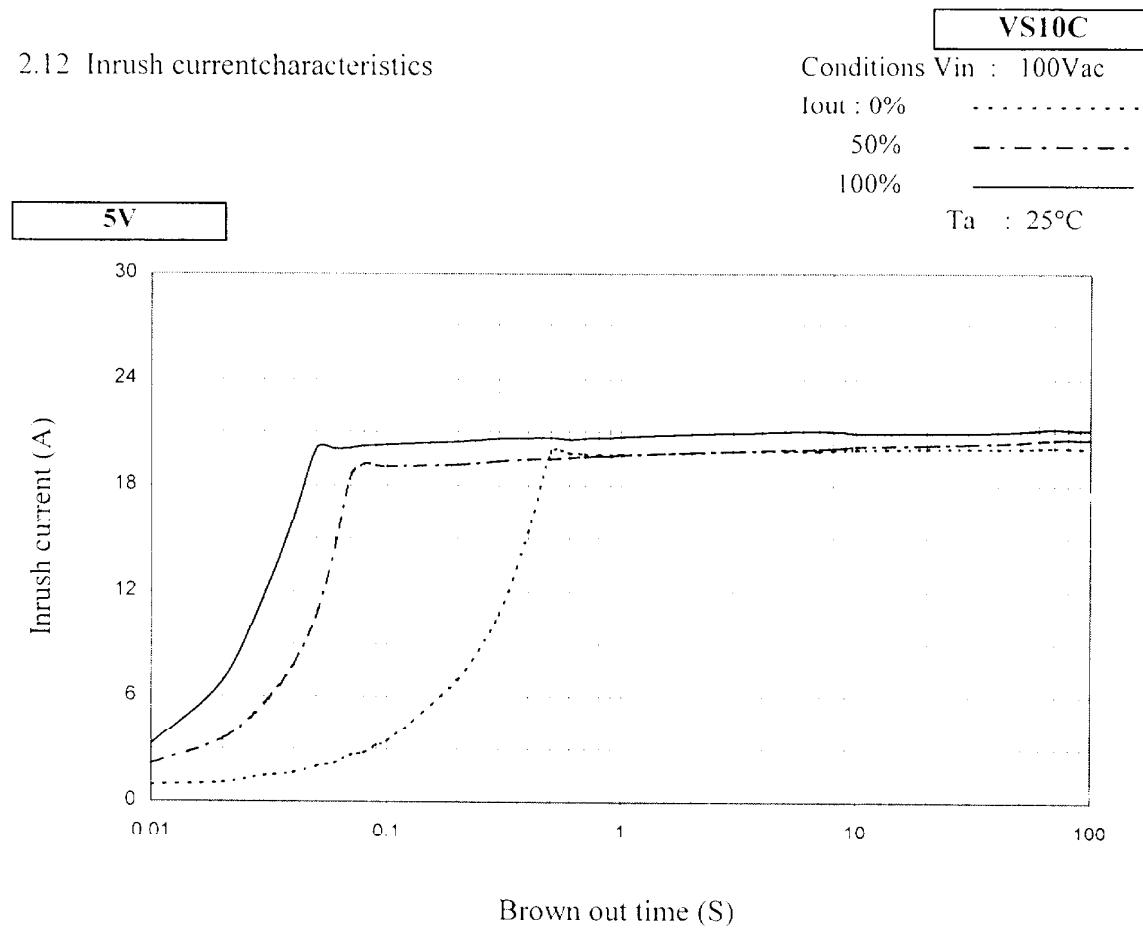
$$\Phi=90^\circ$$



10.0A/DIV

20mS/DIV

2.12 Inrush current characteristics

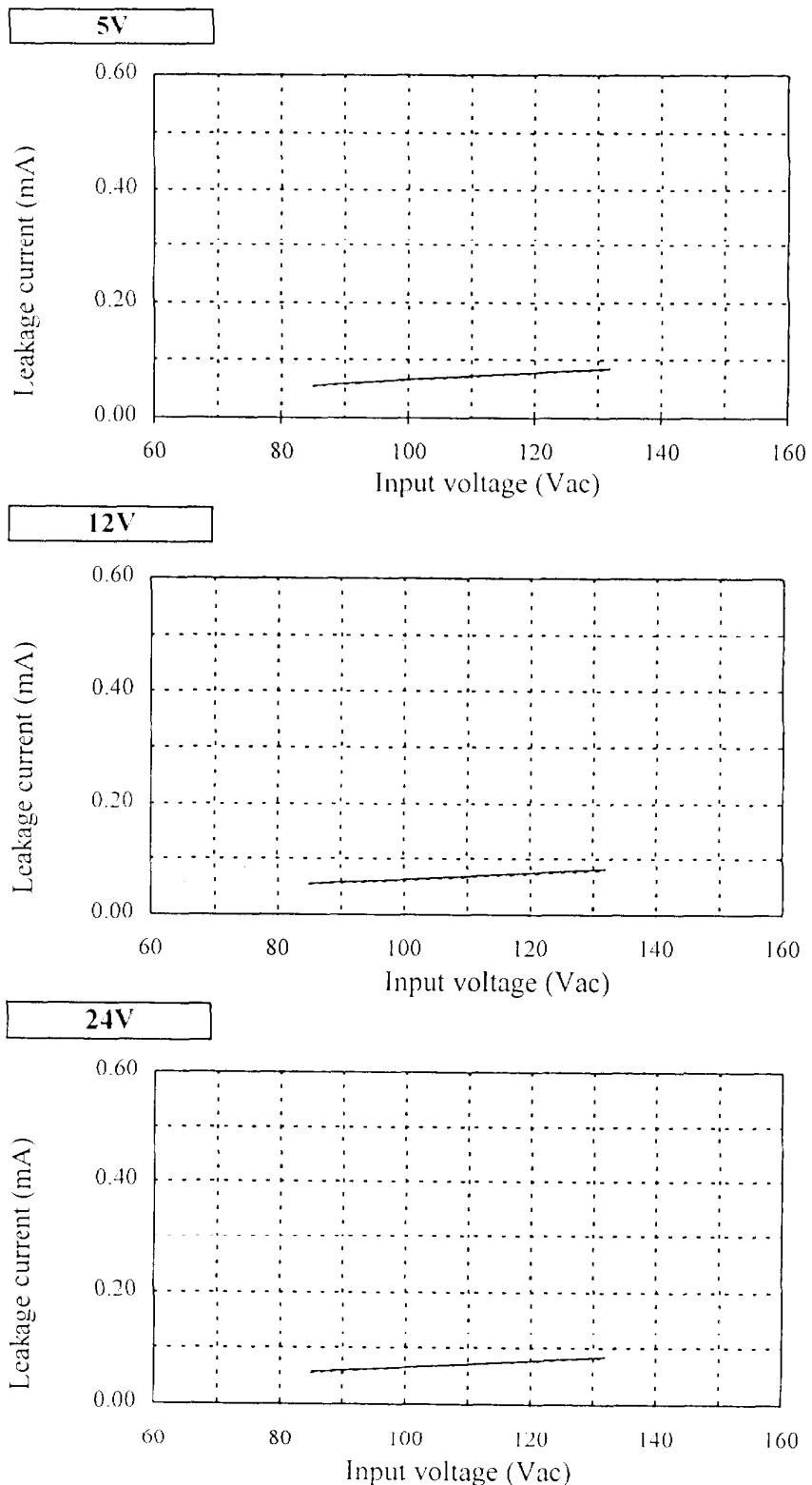


VS10C

Conditions Ta : 25°C

Vin : 0%
100% _____

2.13 Leakage current characteristics

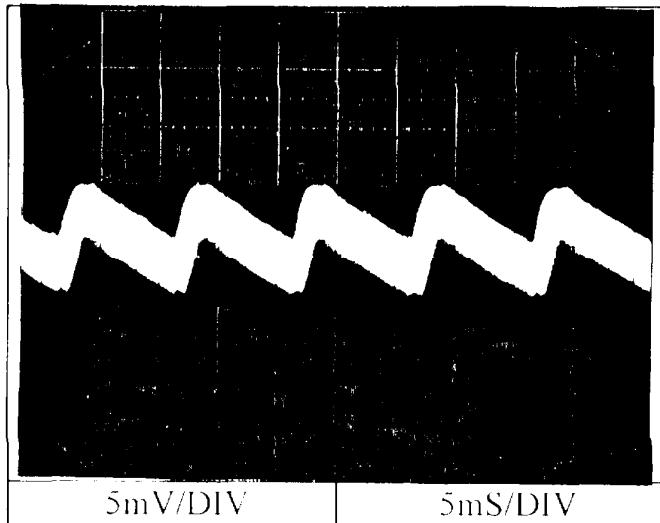


2.14 Output ripple and noise waveform

Conditions Vin : 100VAC
Iout : 100%
Ta : 25°C

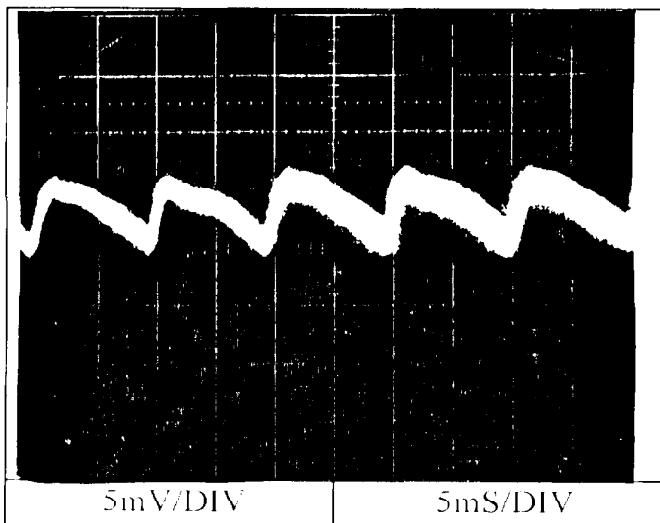
NORMAL MODE

5V



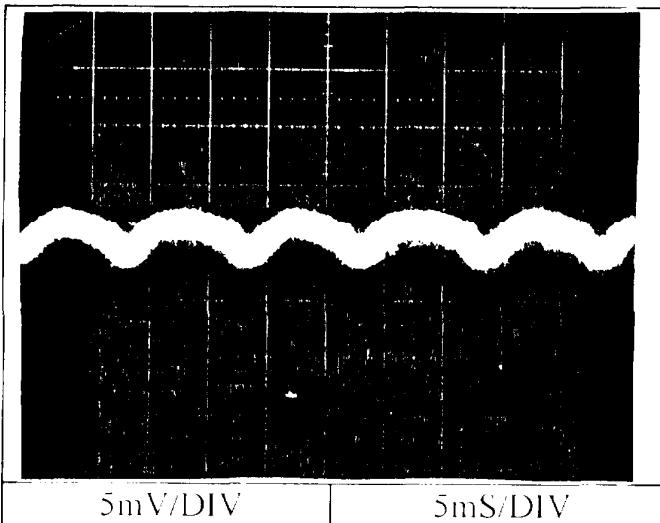
← Vout

12V



← Vout

24V

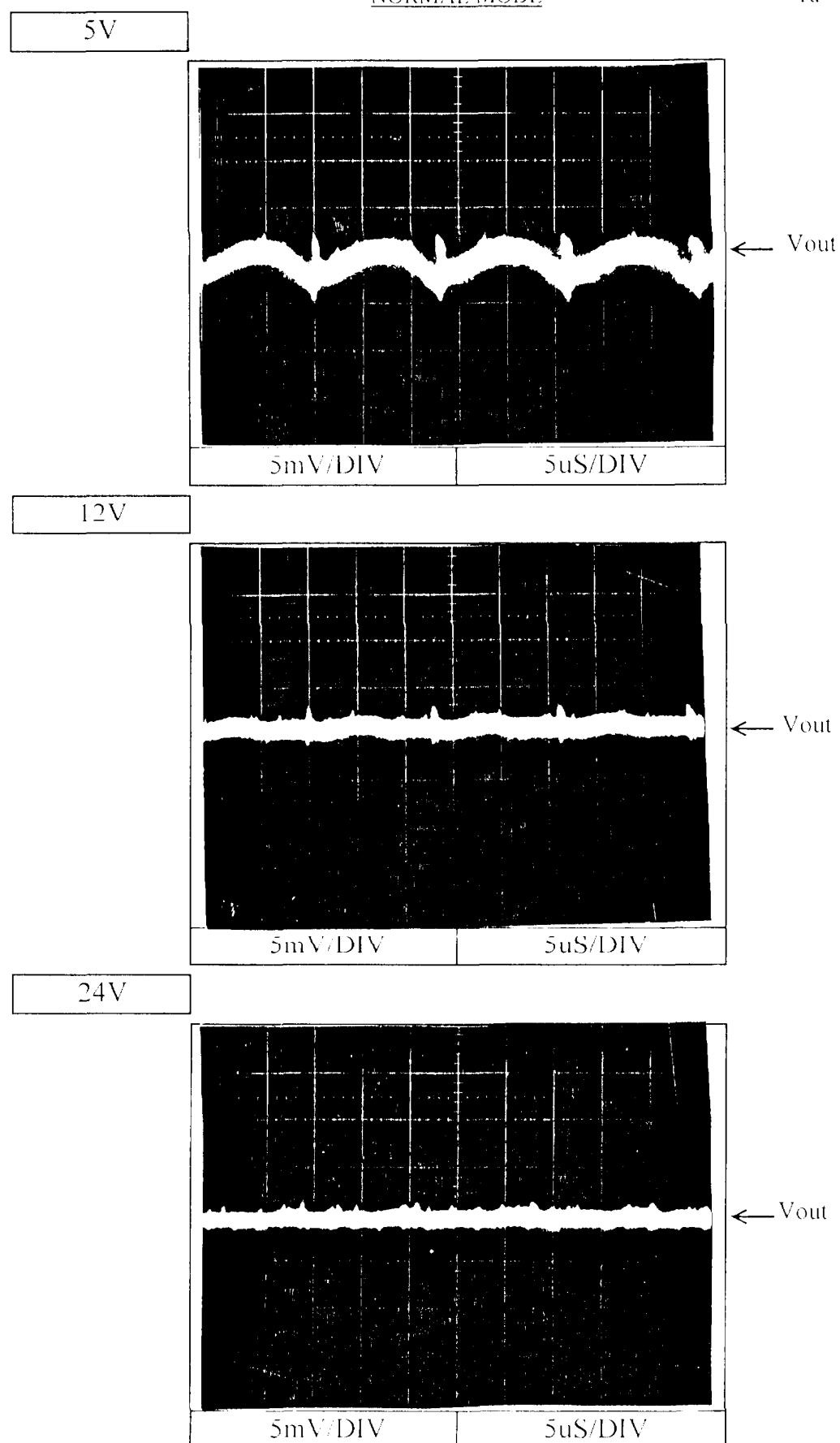


← Vout

2.14 Output ripple and noise waveform

Conditions
Vin : 100VAC
Iout : 100%
Ta : 25°C

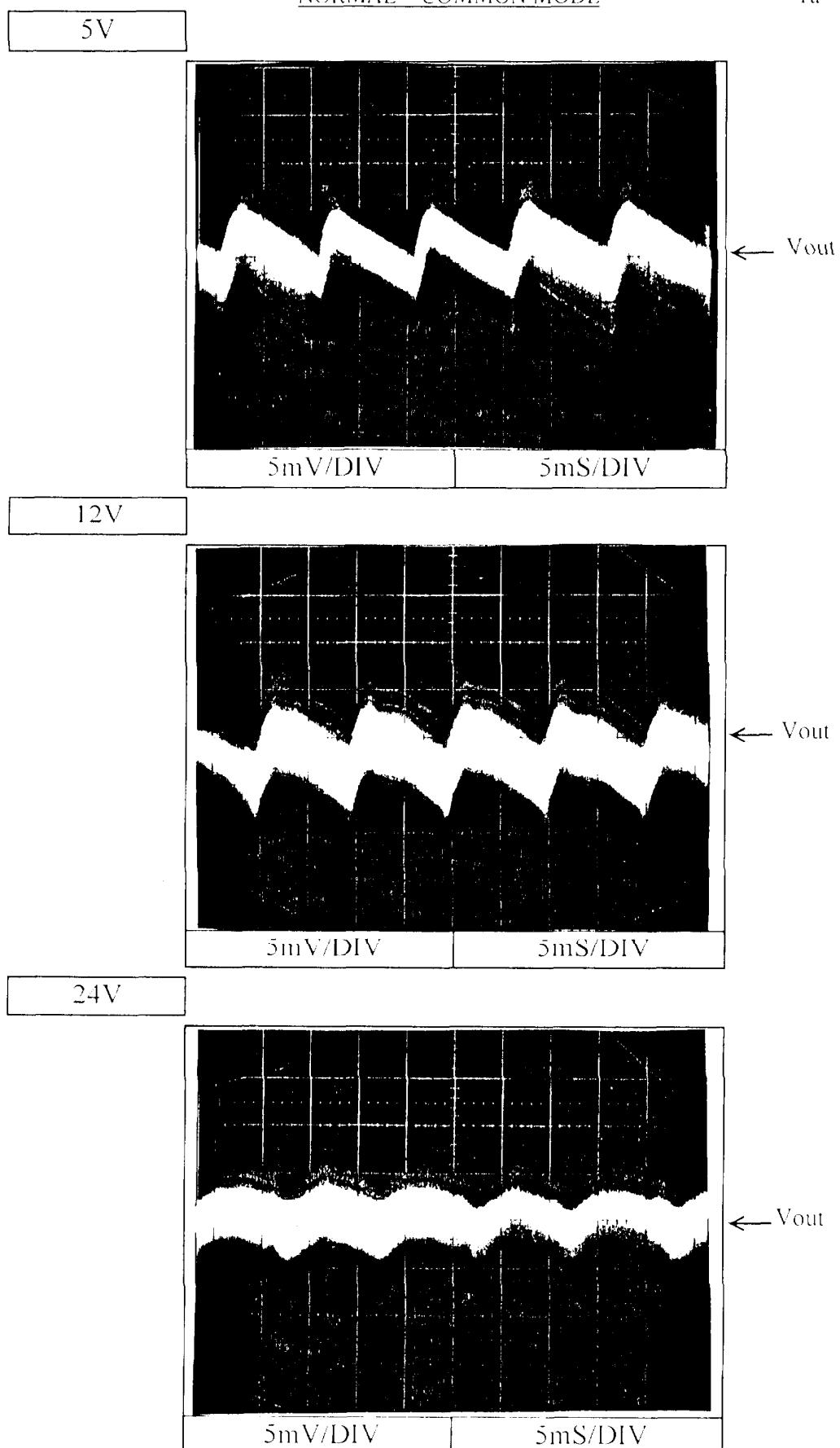
NORMAL MODE



2.14 Output ripple and noise waveform

Conditions Vin : 100VAC
 Iout : 100%
 Ta : 25°C

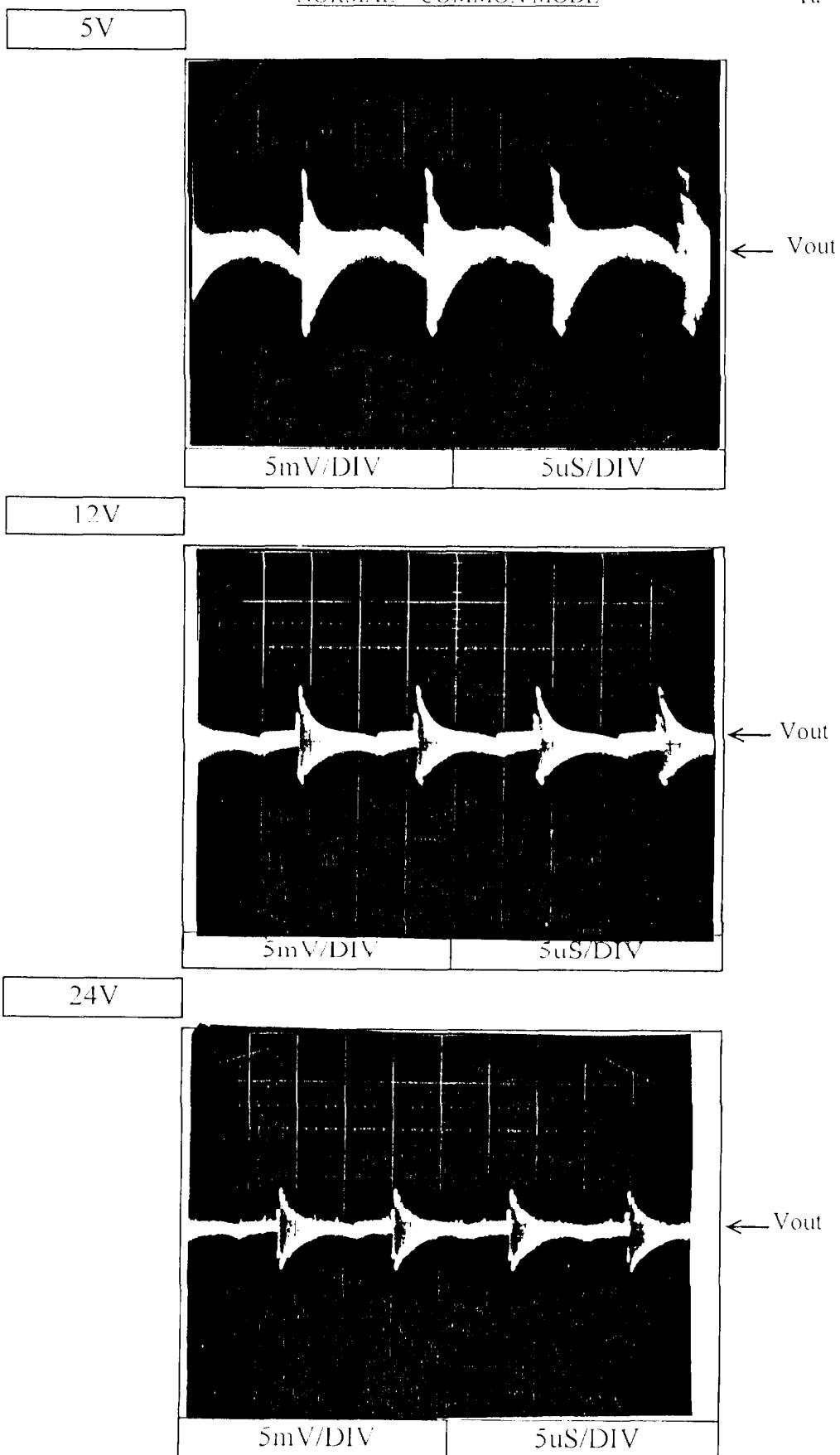
NORMAL + COMMON MODE



2.14 Output ripple and noise waveform

Conditions Vin : 100VAC
 Iout : 100%
 Ta : 25°C

NORMAL + COMMON MODE



VS10C

2.15 Electro Magnetic Interference characteristics

Conditions Vin : 100Vac

Iout : 100%

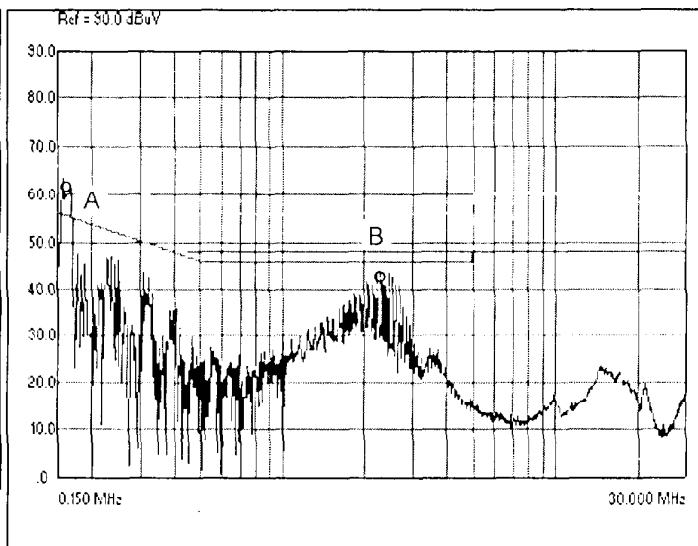
Ta : 25°C

Conducted Emission

5V

Point A		
Ref.	(159.2kHz)	
Data	Limit (dBuV)	Measure (dBuV)
QP	65.55	60.9
AV	55.55	44.3

Point B		
Ref.	(2.29MHz)	
Data	Limit (dBuV)	Measure (dBuV)
QP	56.00	40.4
AV	46.00	14.8

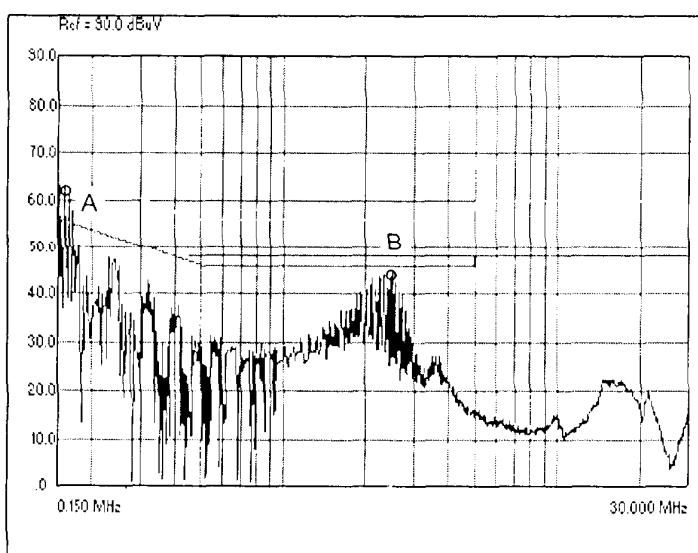


Phase : L

5V

Point A		
Ref.	(152.8kHz)	
Data	Limit (dBuV)	Measure (dBuV)
QP	65.86	62.0
AV	55.86	41.2

Point B		
Ref.	(2.46MHz)	
Data	Limit (dBuV)	Measure (dBuV)
QP	56.00	39.4
AV	46.00	14.5



Phase : N

VS10C

2.15 Electro Magnetic Interference characteristics

Conditions Vin : 100Vac

Iout : 100%

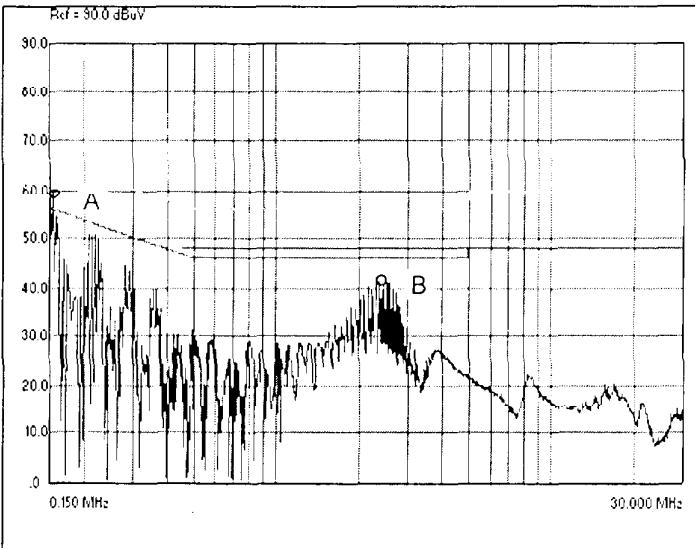
Conducted Emission

Ta : 25°C

12V

Point A Ref. (154.2kHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	65.79	57.8
AV	55.79	37.9

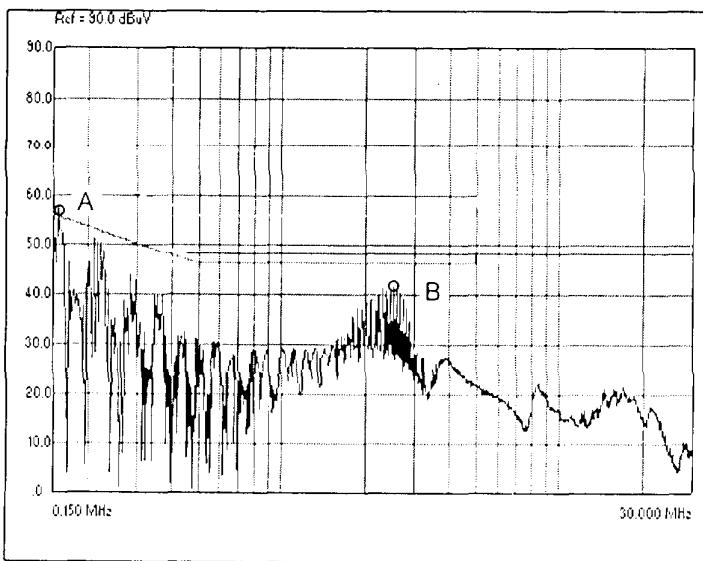
Point B Ref. (2.37MHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	56.00	37.2
AV	46.00	15.3



12V

Point A Ref. (154.7kHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	65.77	57.0
AV	55.77	36.1

Point B Ref. (2.51MHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	56.00	36.3
AV	46.00	15.0



VS10C

2.15 Electro-Magnetic Interference characteristics

Conditions Vin : 100Vac

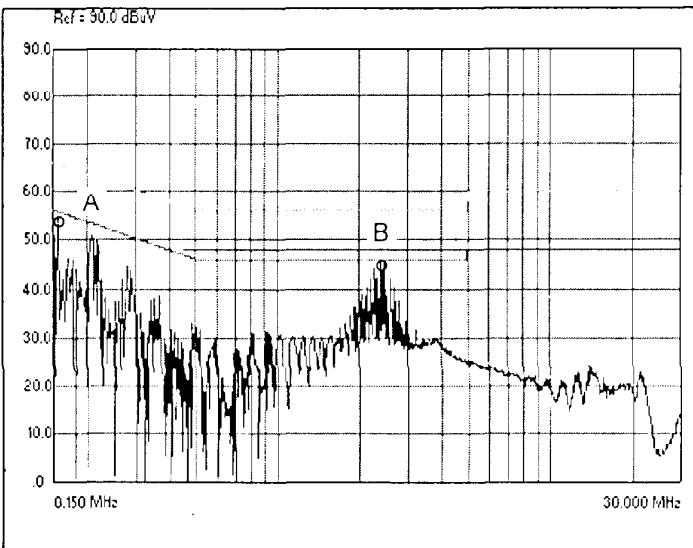
Iout : 100%

Ta : 25°C

Conducted Emission

24V

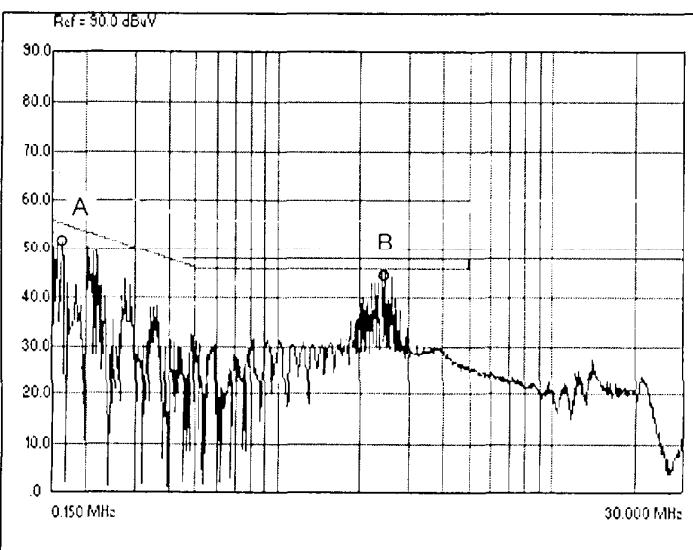
Point A Ref. (155.4kHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	65.73	50.9
AV	55.73	29.9



Phase : L

24V

Point A Ref. (160.1kHz)		
Data	Limit (dBuV)	Measure (dBuV)
QP	65.53	49.4
AV	55.53	27.5



Phase : N

VS10C

2.15 Electro Magnetic Interference characteristics

Conditions Vin : 100Vac

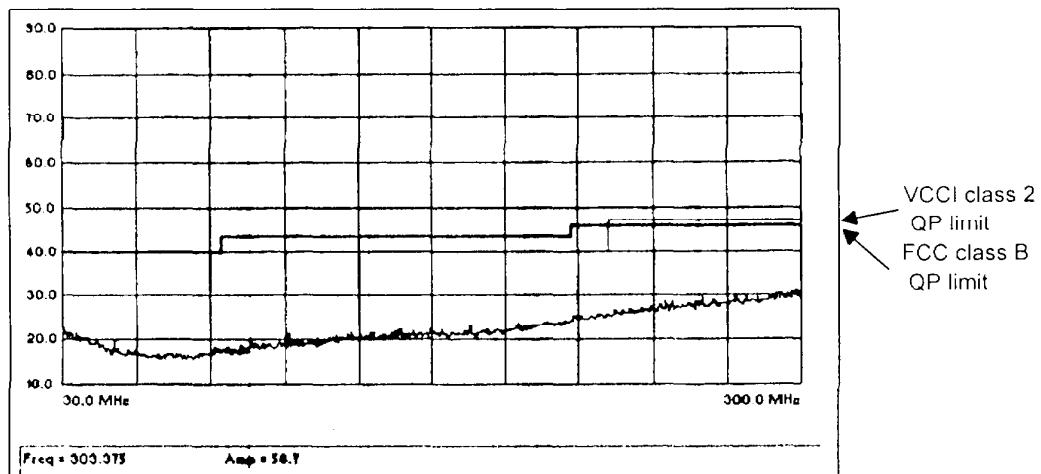
Iout : 100%

Ta : 25°C

Radiated Emission Noise

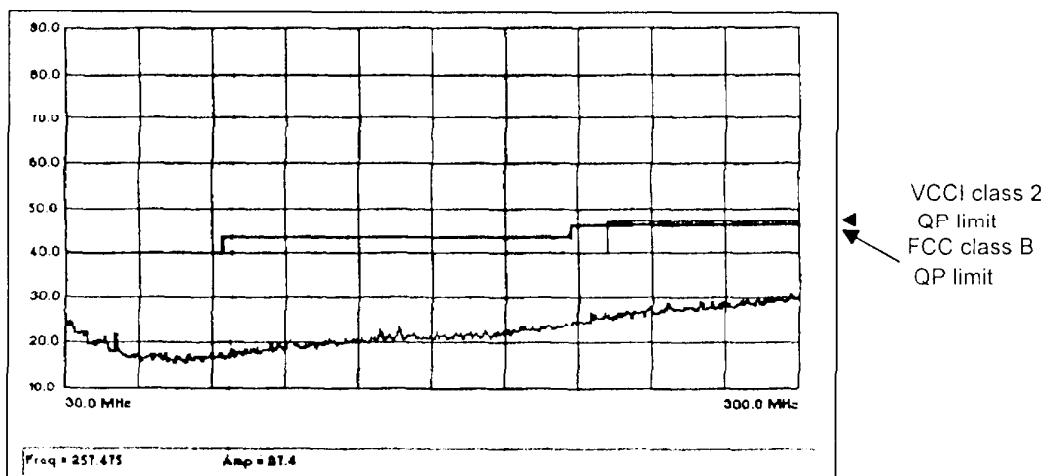
5V

HORIZONTAL :



5V

VERTICAL :



VS10C

2.15 Electro Magnetic Interference characteristics

Conditions Vin : 100Vac

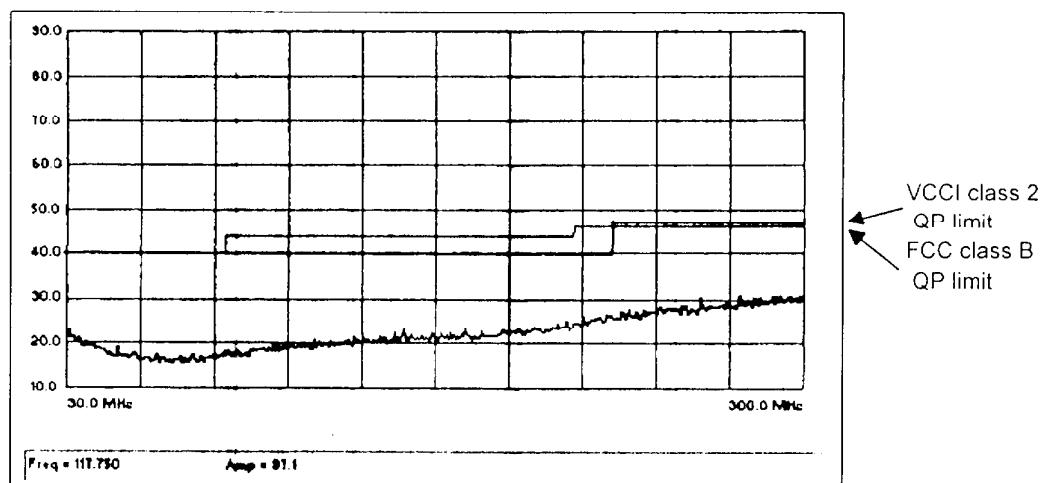
Iout : 100%

Ta : 25°C

Radiated Emission Noise

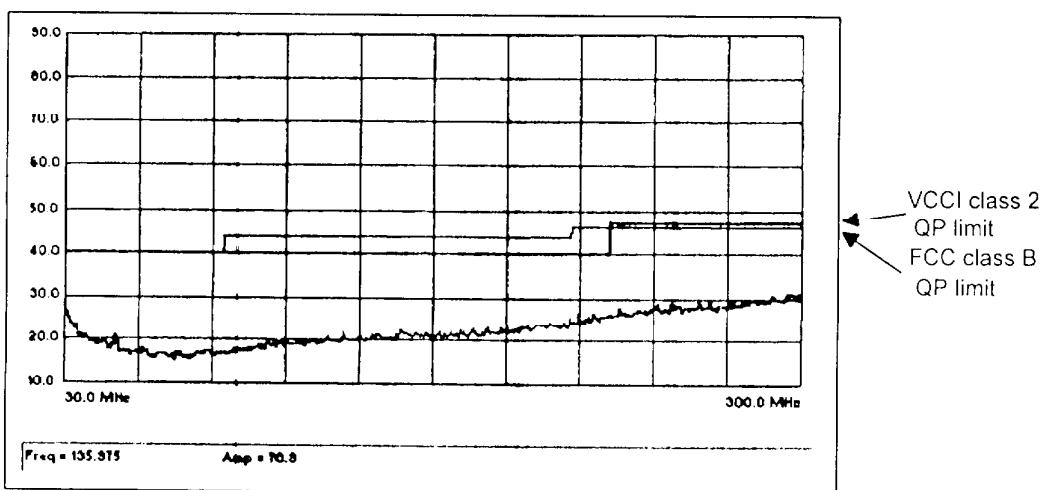
12V

HORIZONTAL :



12V

VERTICAL :



VS10C

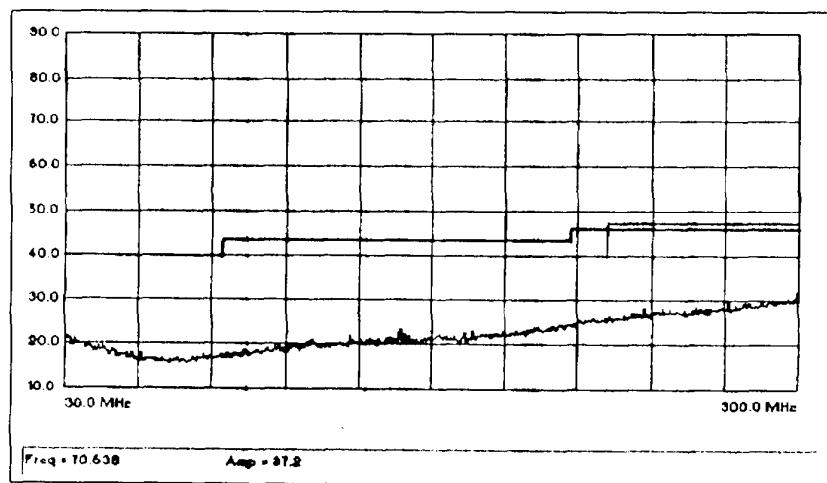
2.15 Electro Magnetic Interference characteristics

Conditions Vin : 100Vac
Iout : 100%
Ta : 25°C

Radiated Emission Noise

24V

HORIZONTAL :



24V

VERTICAL :

